ESE370: Circuit-Level Modeling, Design, and Optimization for Digital Systems

Lec 2: January 18, 2023

Transistor Introduction and

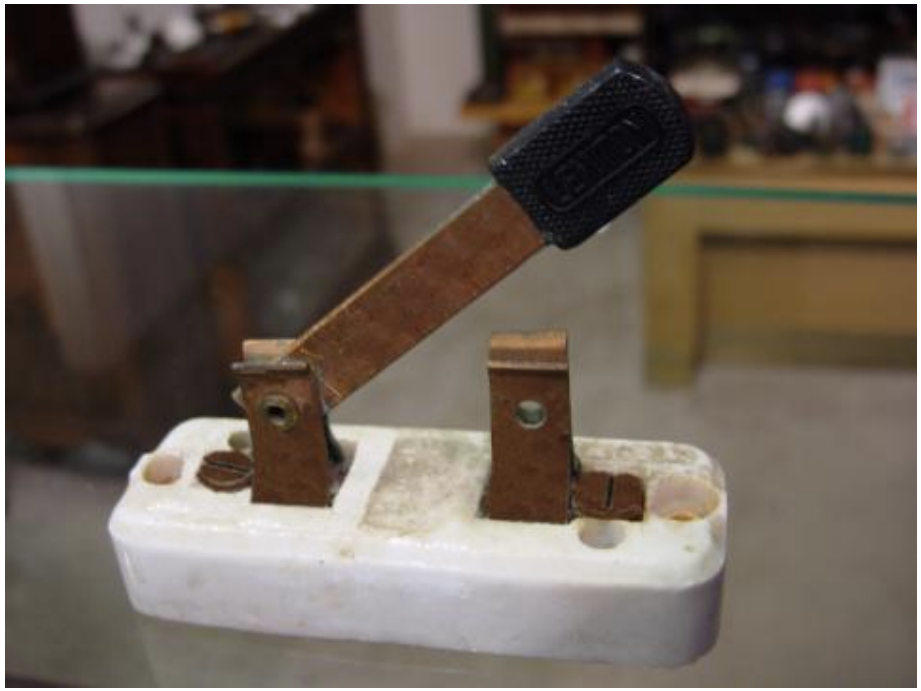
Gates from Transistors

Today

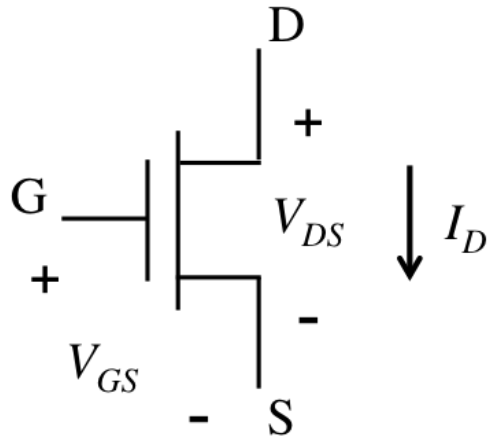
- Transistors – MOSFET
- Zero-th order transistor model
  - Good enough for [what?]
- Basic Digital Gates
- Boolean Logic
  - Basic Algebra
  - Minimum Sum of Products/K-maps
- How to construct static CMOS gates
  - Gate function identification (preclass)
  - CMOS gate structure
    - Pullup/pulldown networks

Transistor

- Electrical switch to conduct electricity
  - Instead of physically connecting conducting materials to conduct electricity, apply a voltage to conduct



MOSFET



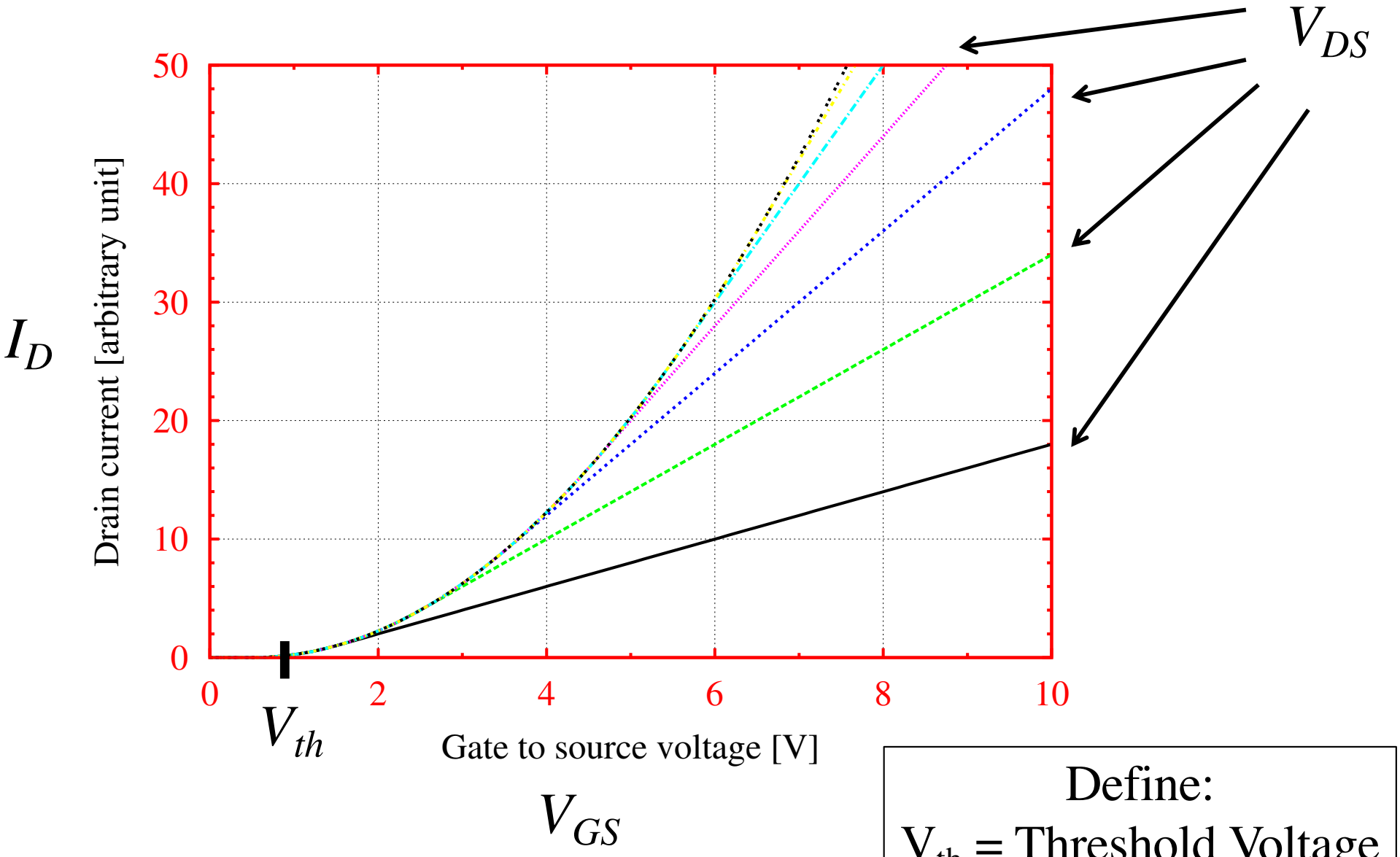
$$V_{GS} = V_G - V_S$$

$$V_{DS} = V_D - V_S$$

$$I_D = f(V_{DS}, V_{GS})$$

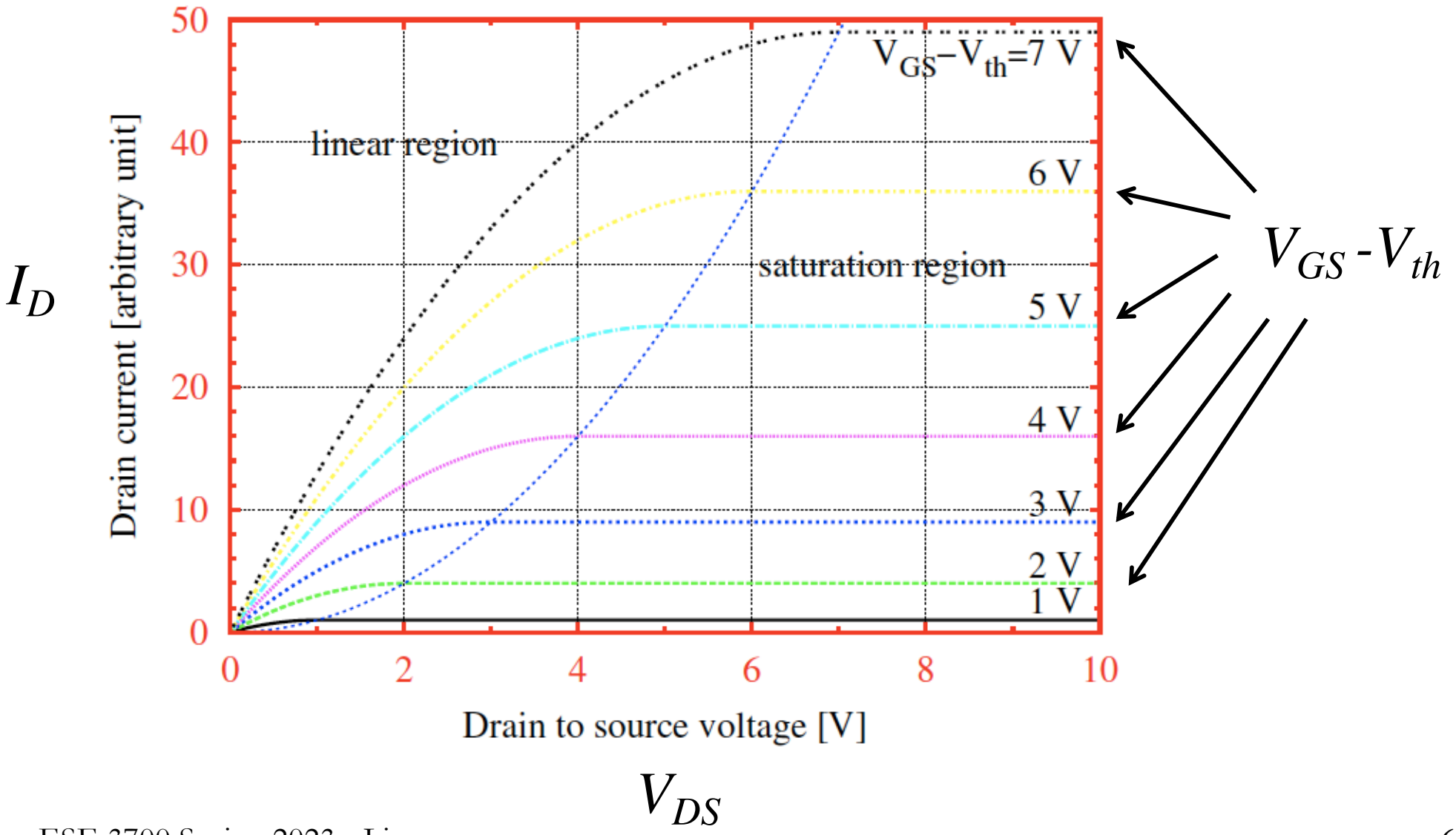
- Metal Oxide Semiconductor Field Effect Transistor
  - Primary **active** component for the term
  - Three terminal device
    - Voltage at gate controls conduction between two other terminals (source, drain)

MOSFET – IV Characteristics

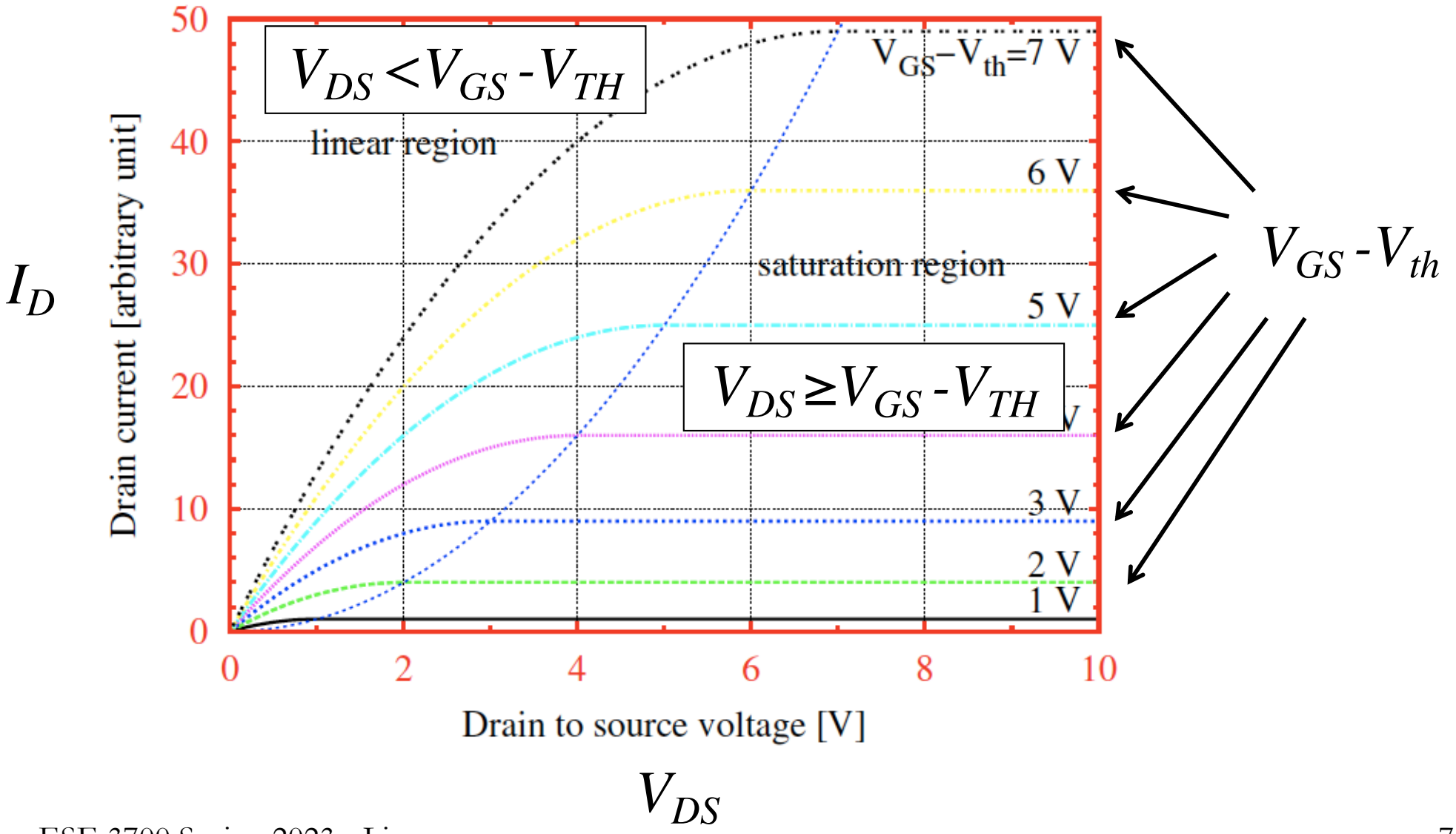


Define:
V_{th} = Threshold Voltage

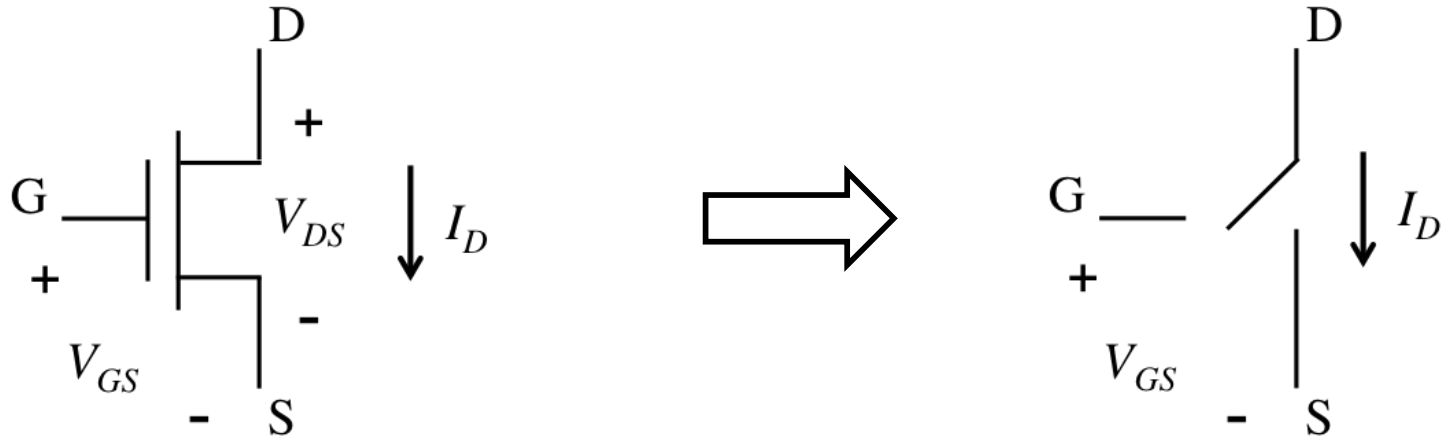
MOSFET – IV Characteristics



MOSFET – IV Characteristics

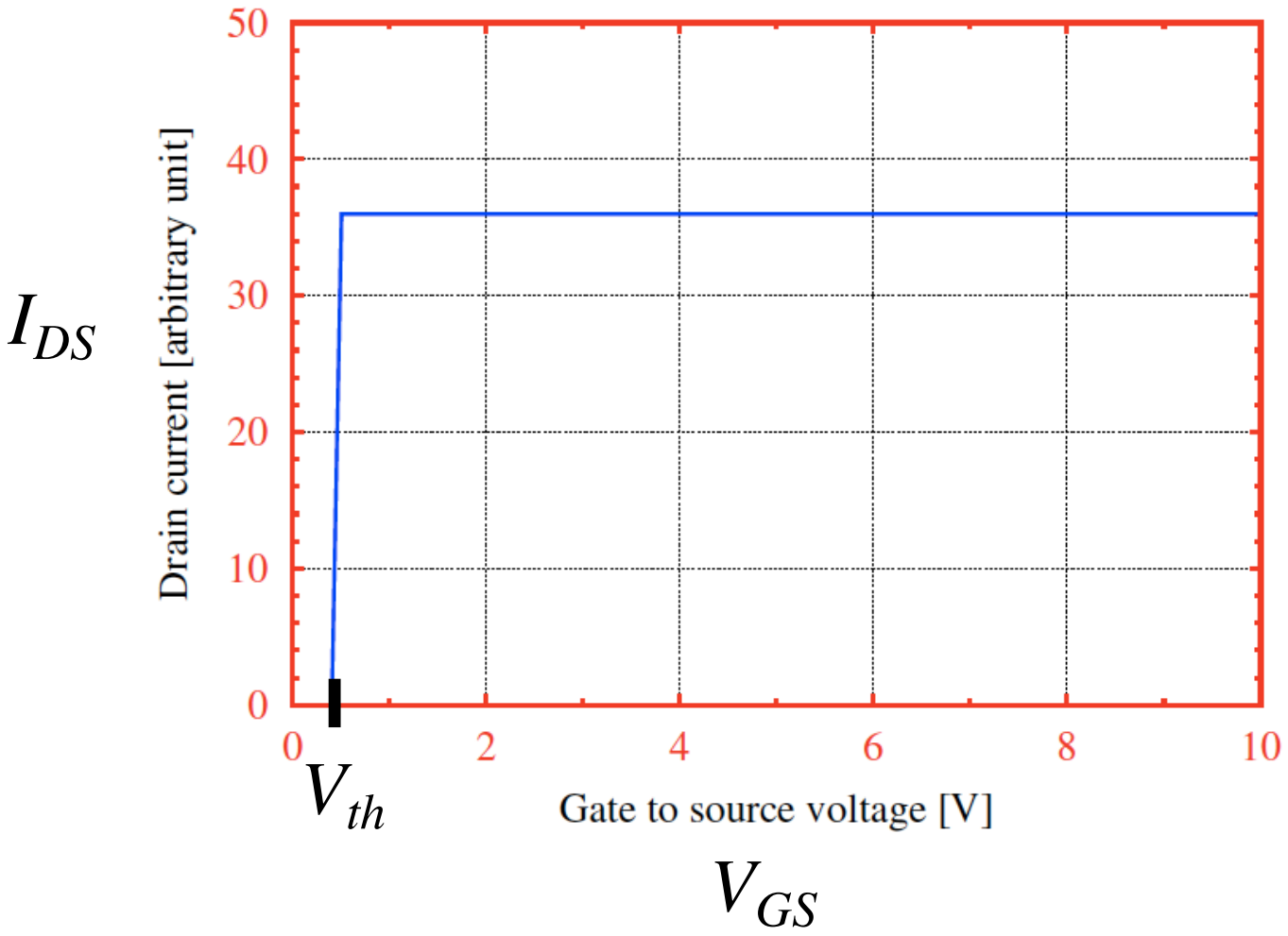


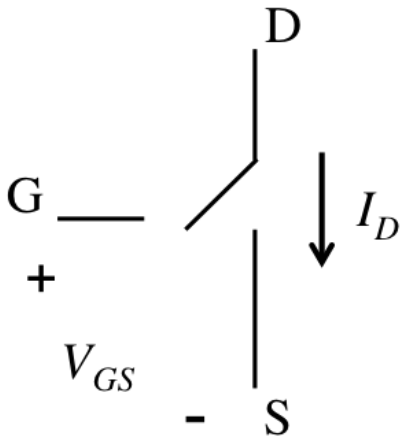
MOSFET – Zeroeth Order Model



- Ideal Switch
  - $V_{GS} > V_{th}$ → switch is closed, conducts
  - $V_{GS} < V_{th}$ → switch is open, does not conduct
- Gate draws no current from input
  - Loads input capacitively (gate capacitance)

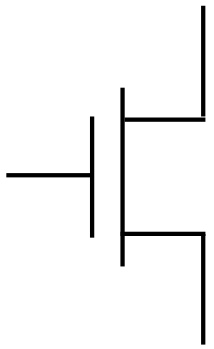
MOSFET – Zeroeth Order Model





MOSFET - Symmetric

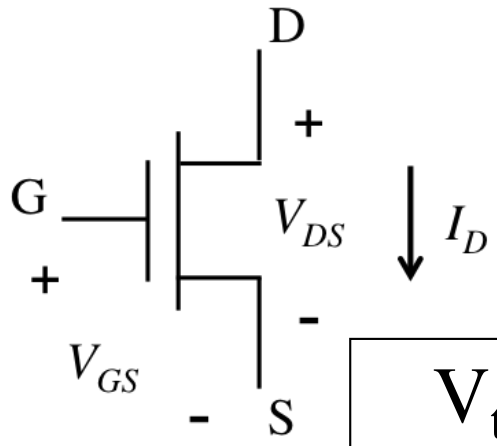
- Switch turned on for positive V_{GS}
  - Which side is drain or source?



MOSFET – N-Type

- Switch turned on for positive V_{GS}

$V_D > V_S$



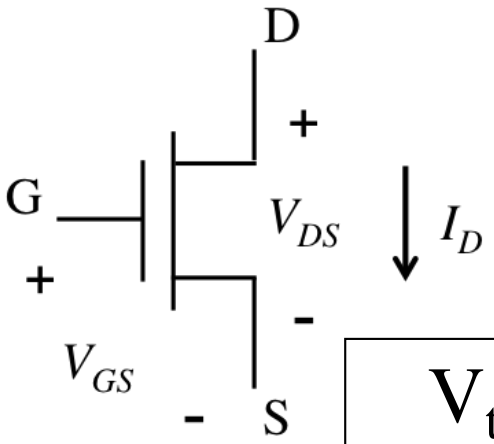
$V_{th,n} > 0$

$V_{GS} > V_{th,n}$ to conduct

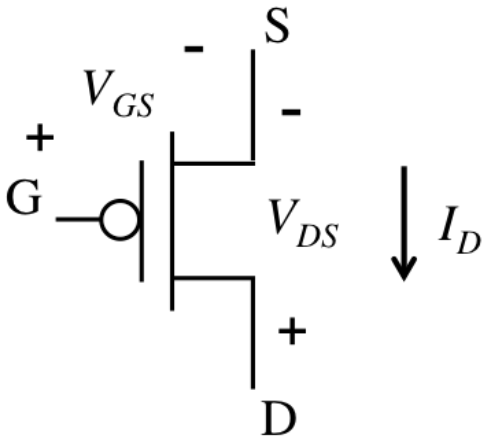
MOSFET – N-Type, P-Type

- Switch turned on for positive V_{GS}
- Switch turned on for negative V_{GS}

$V_D > V_S$



$V_S > V_D$



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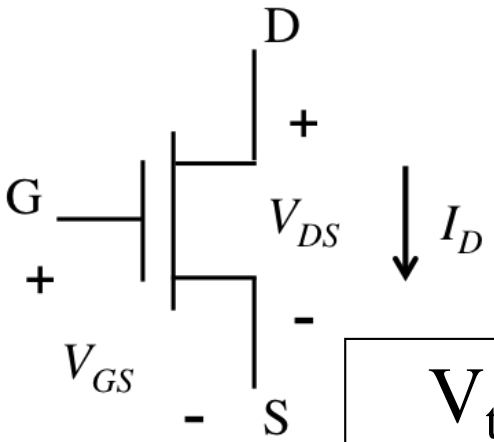
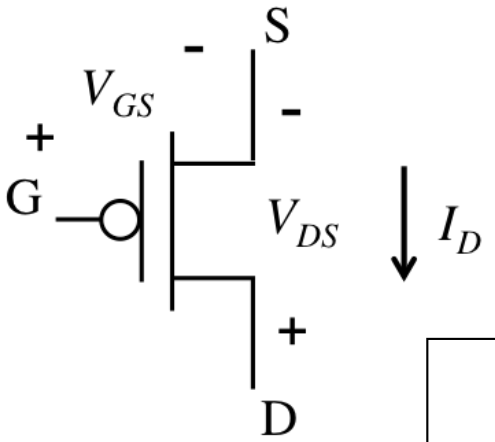


$V_{th,n} > 0$

$V_{GS} > V_{th,n}$

to conduct

$V_S > V_D$



$V_{th,p} < 0$

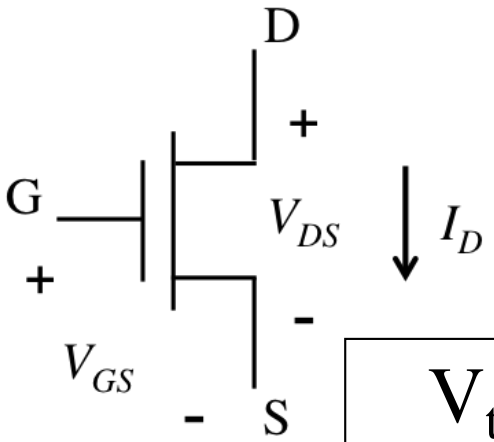
$V_{GS} < V_{th,p}$

to conduct

MOSFET – N-Type, P-Type

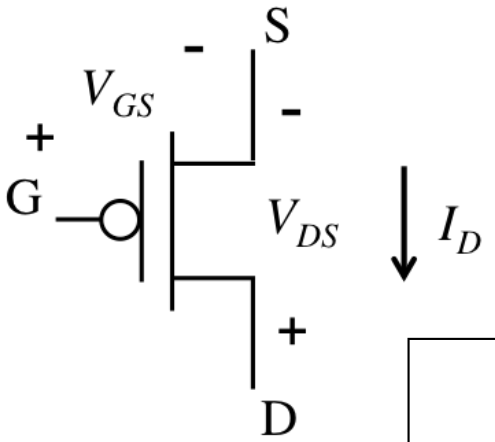
- Switch turned on for positive V_{GS}
- Switch turned on for negative V_{GS}

$V_D > V_S$



$V_{th,n} > 0$
$V_{GS} > V_{th,n}$
to conduct

$V_S > V_D$

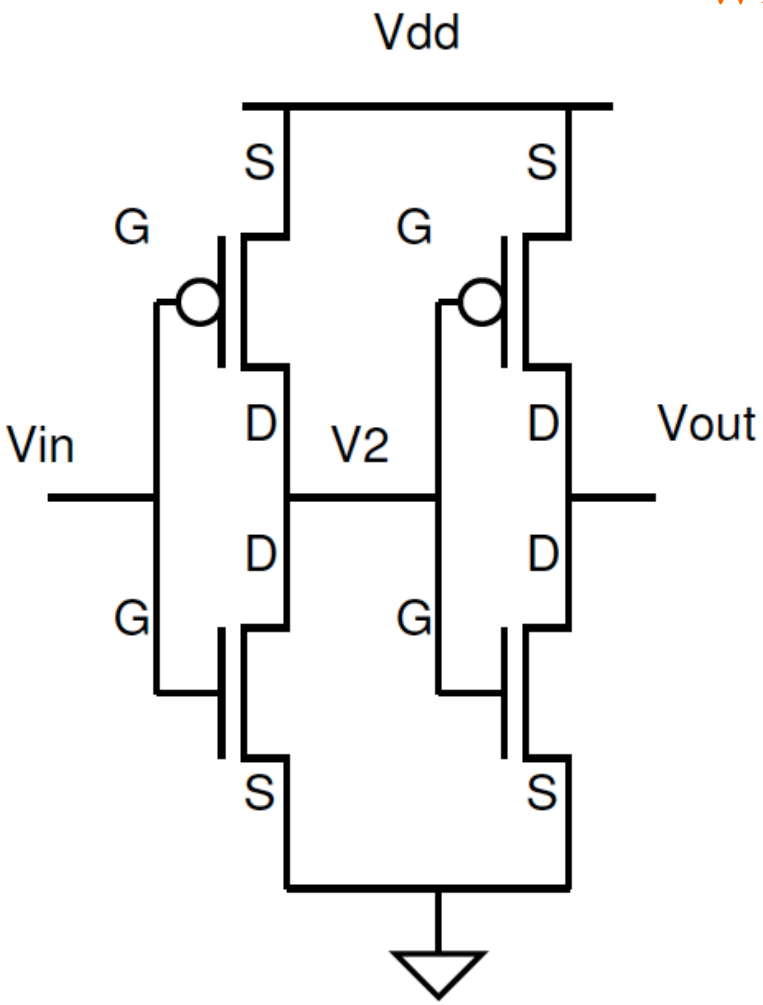


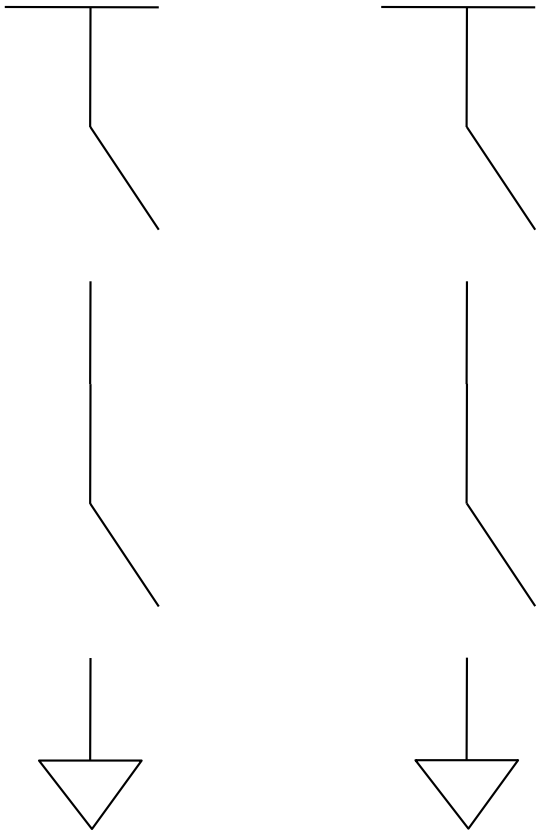
$|V_{th,p}| > 0$
$|V_{GS}| > |V_{th,p}|$
to conduct

Apply zero-order model

Note S, D annotation on this slide (won't be labeled in future)

Why is it this way?

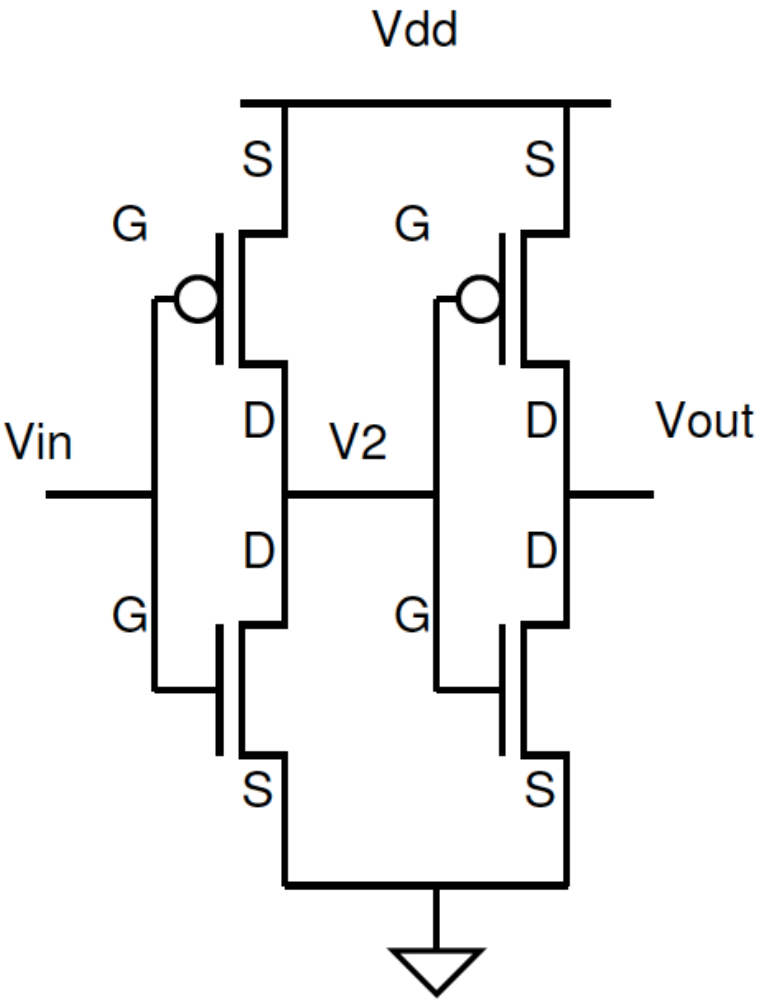


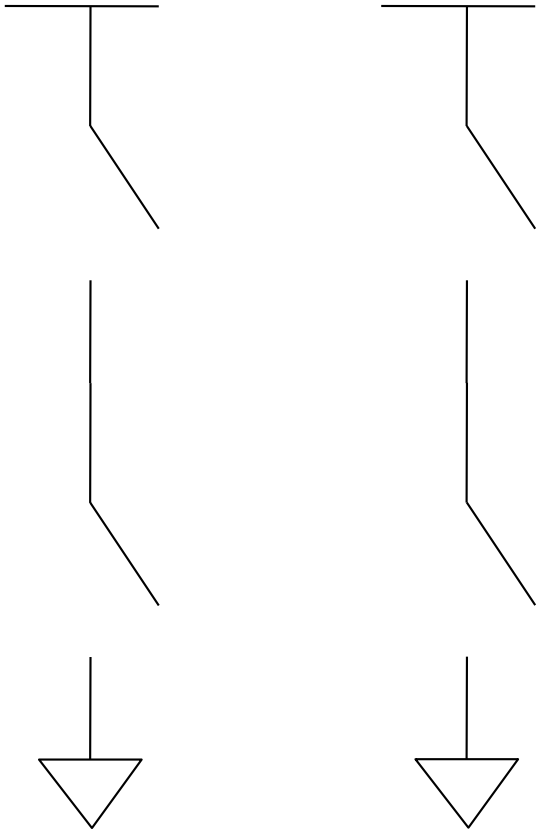


Apply zero-order model?

What happens when $V_{in} = V_{dd} > V_{thn}$?

$$V_{th,p} = -V_{th,n}$$
$$V_{GS} = V_G - V_S$$





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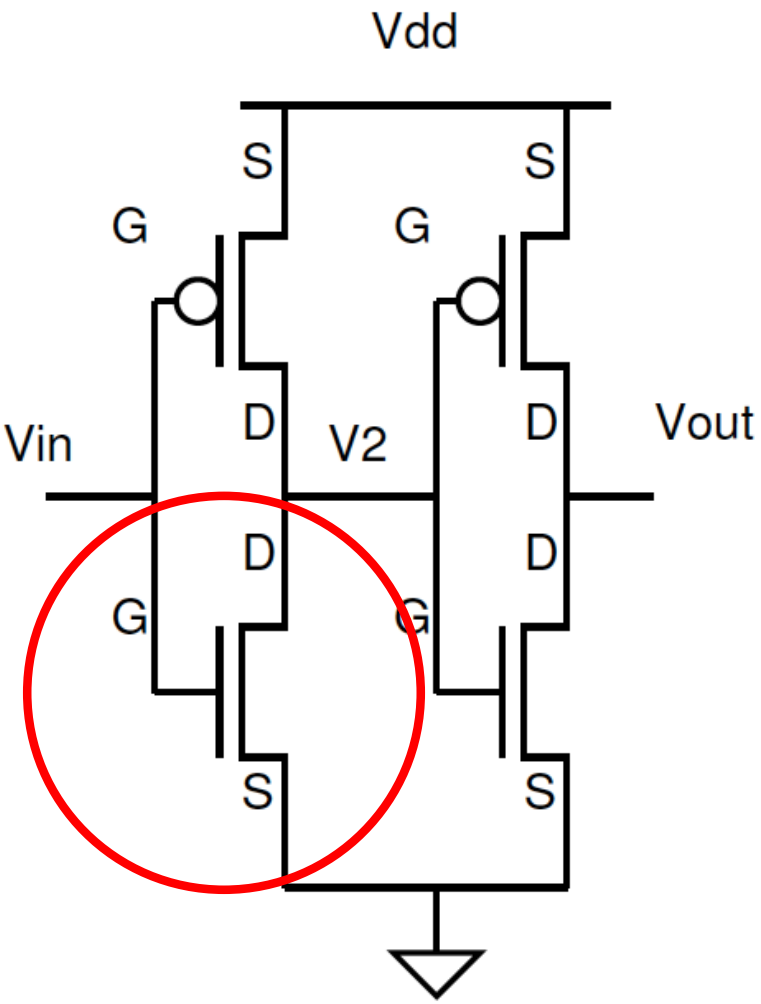

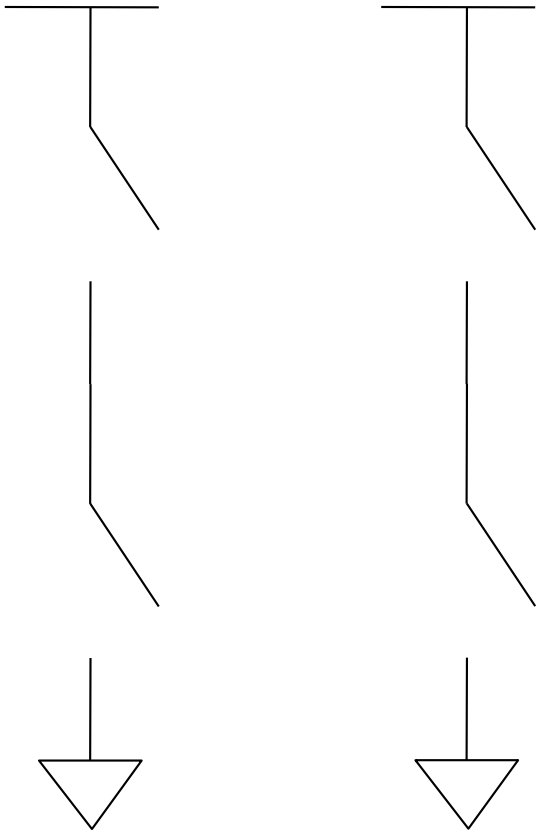

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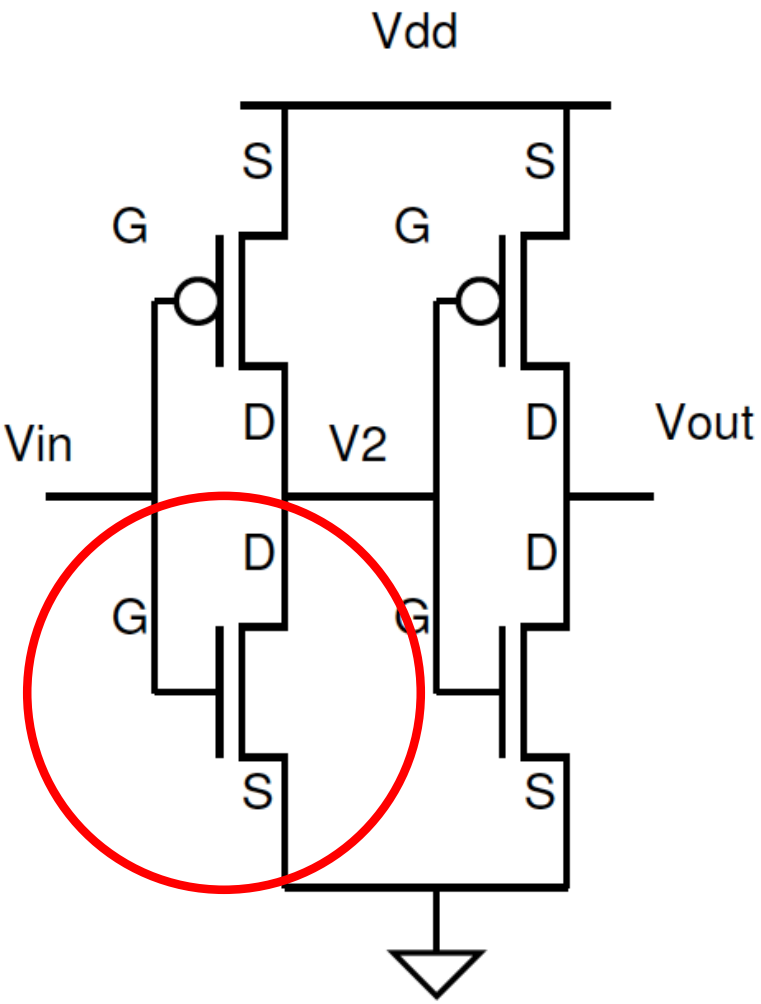

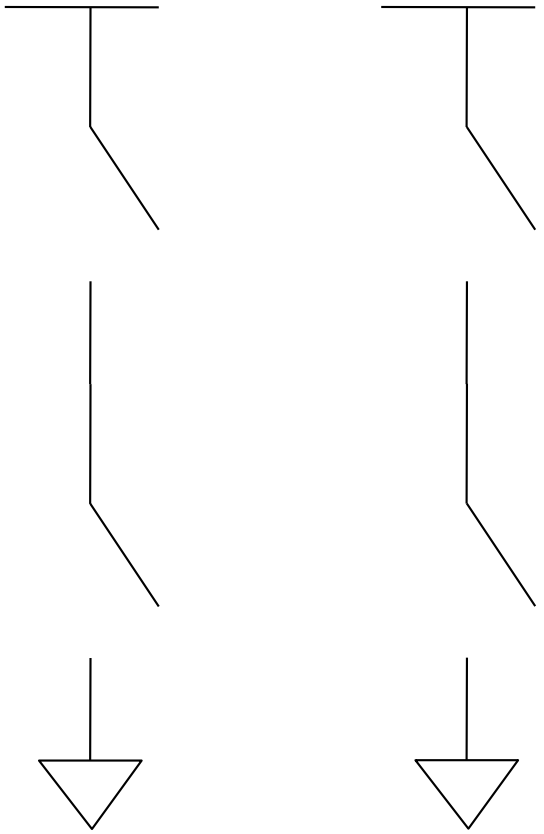

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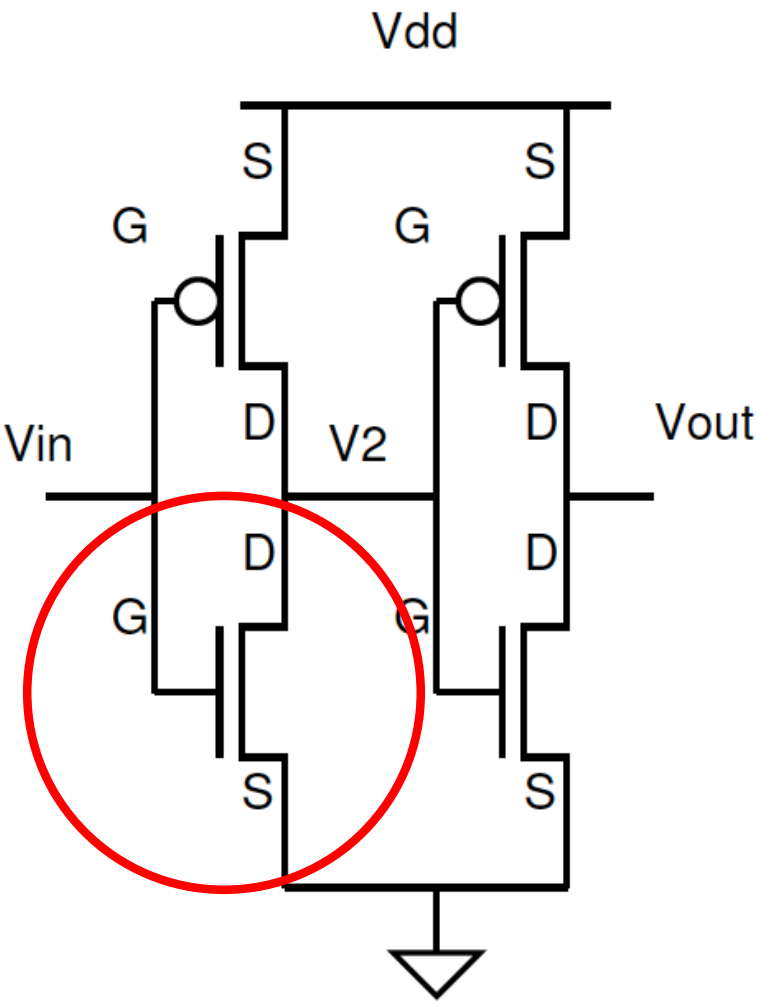

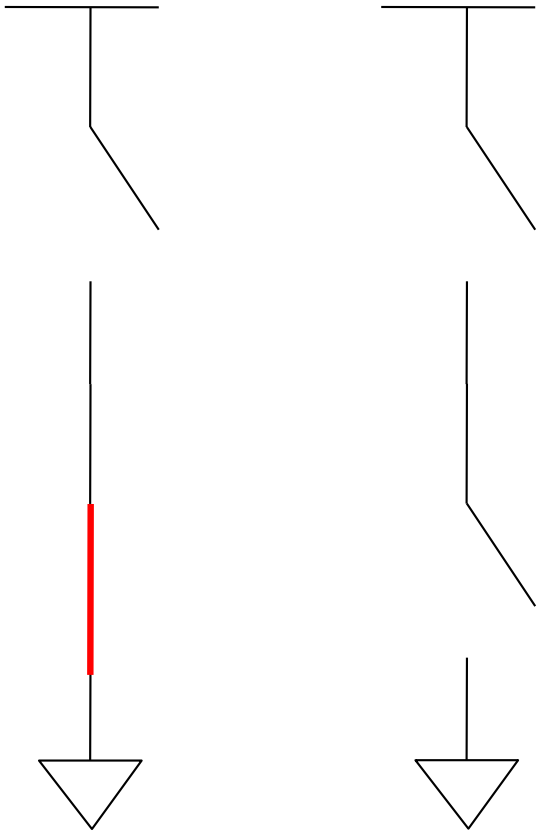

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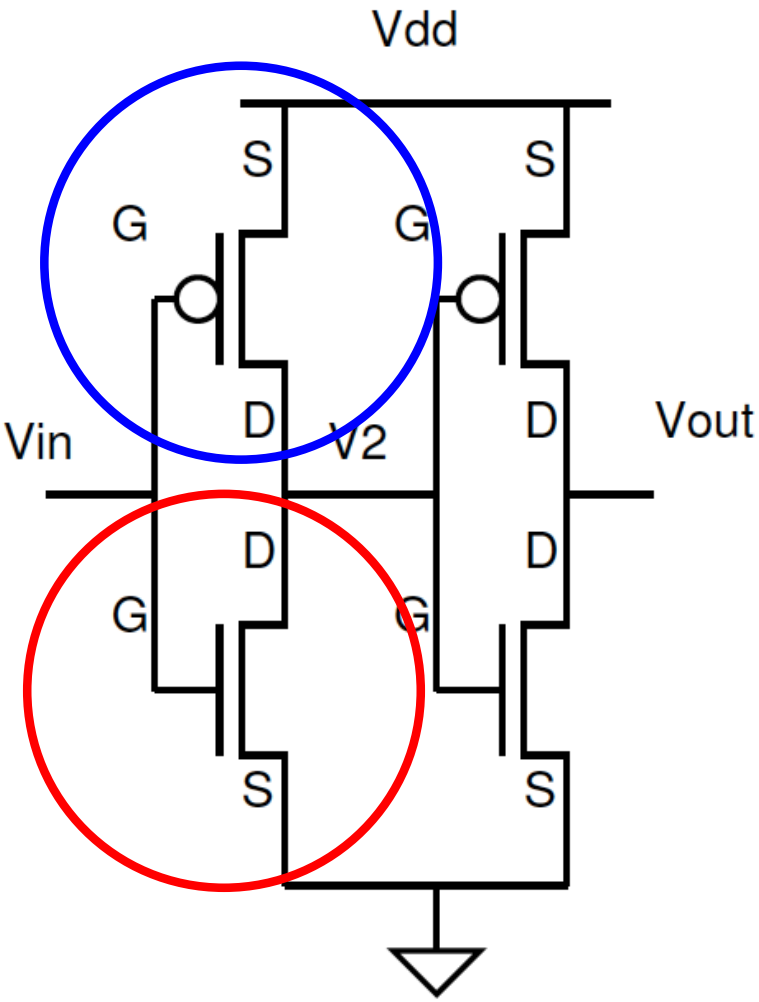

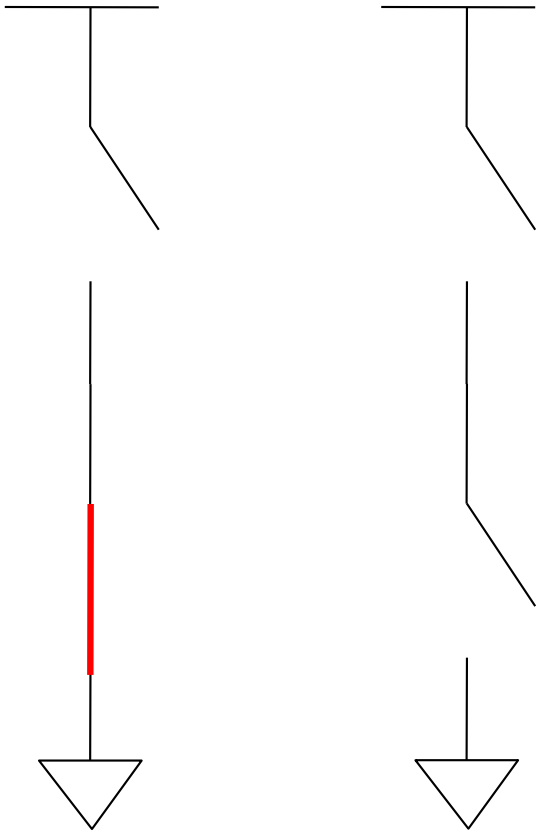

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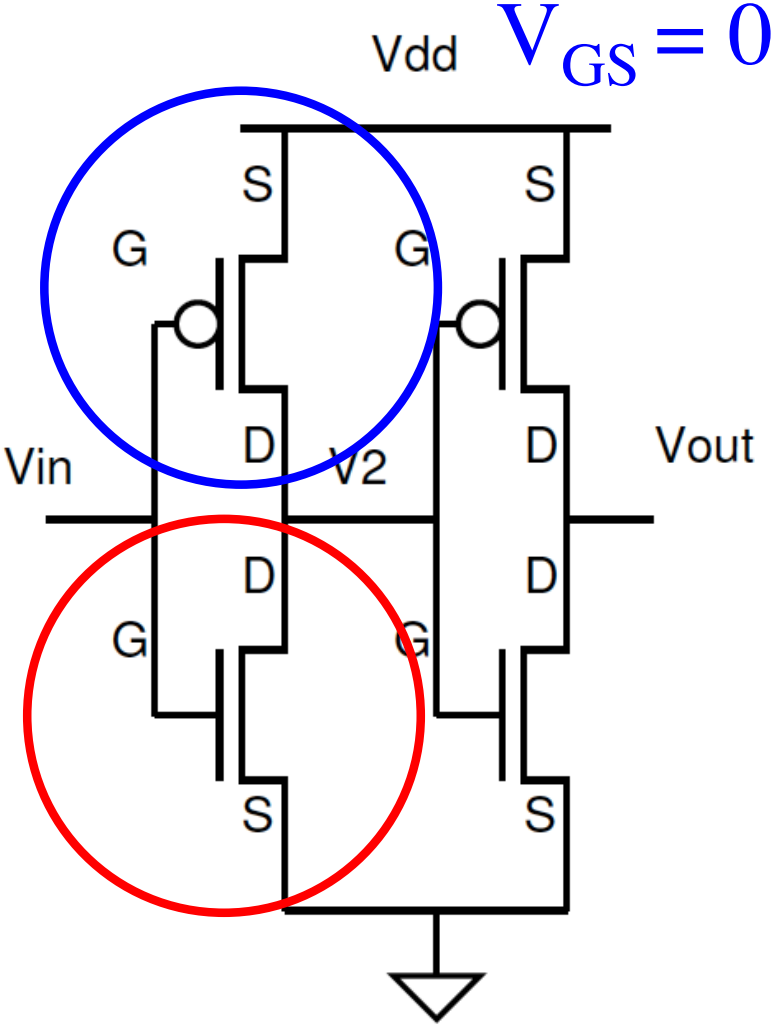
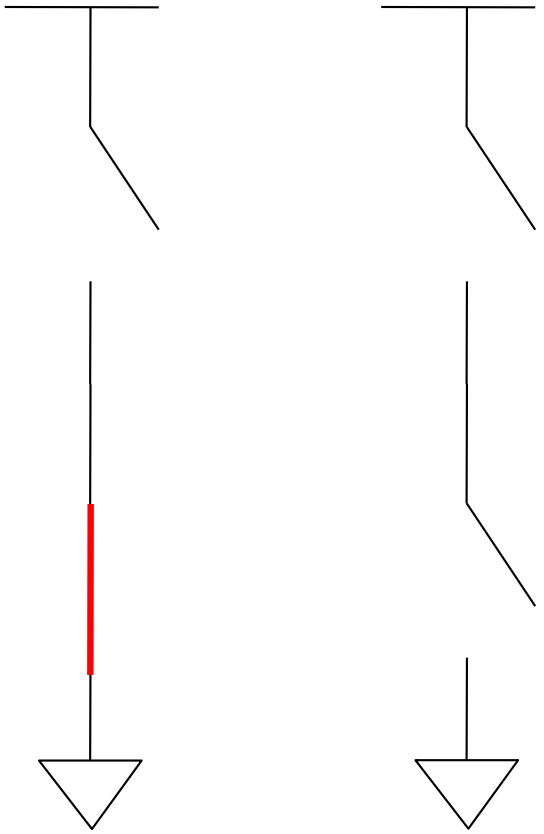


$V_{GS} = 0 > V_{th,p}$



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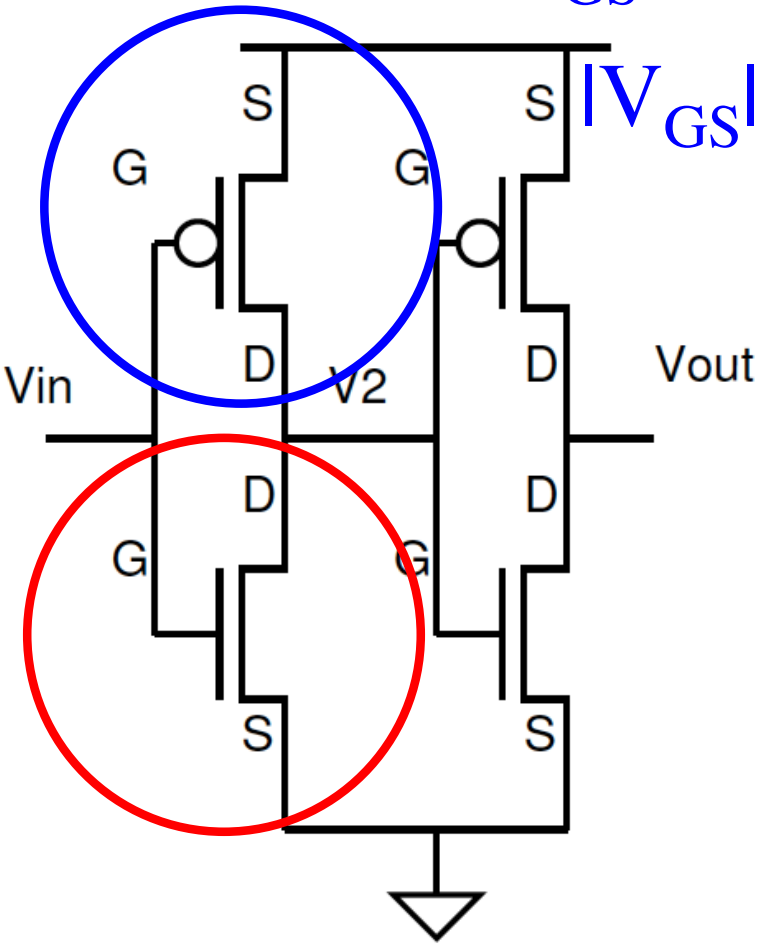

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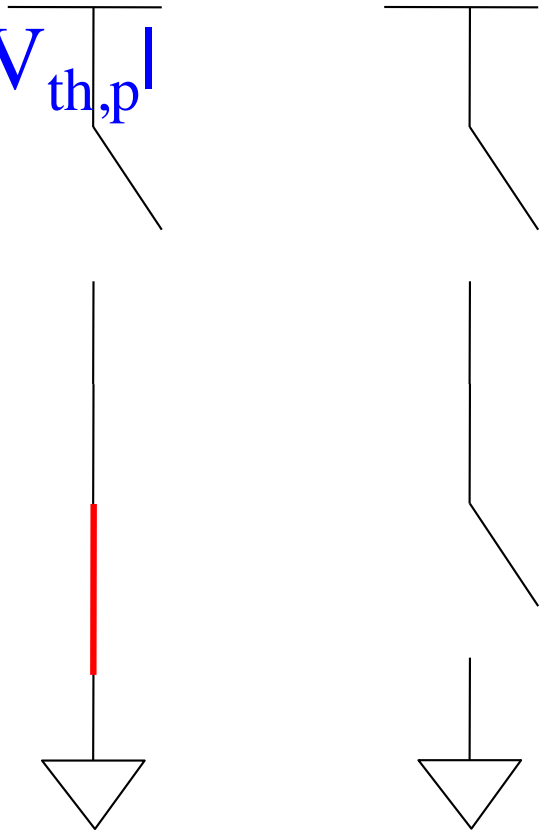

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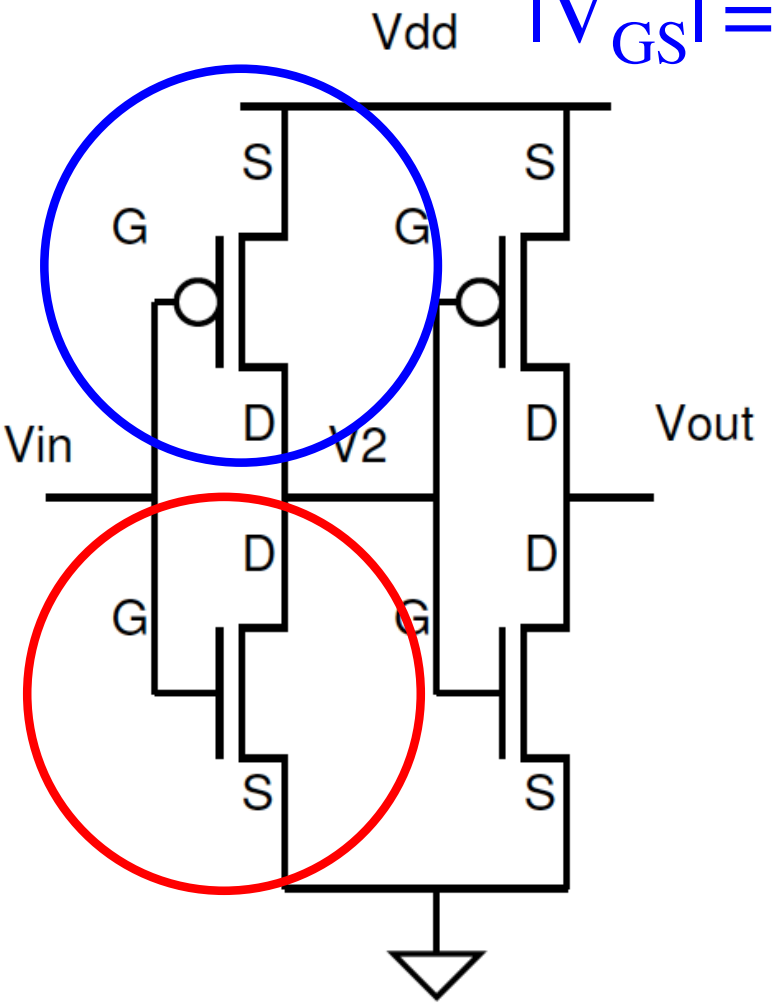

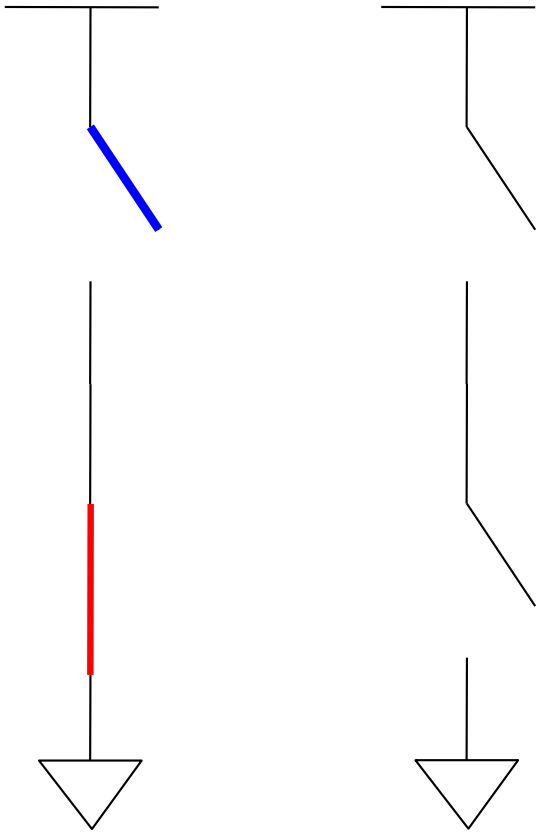

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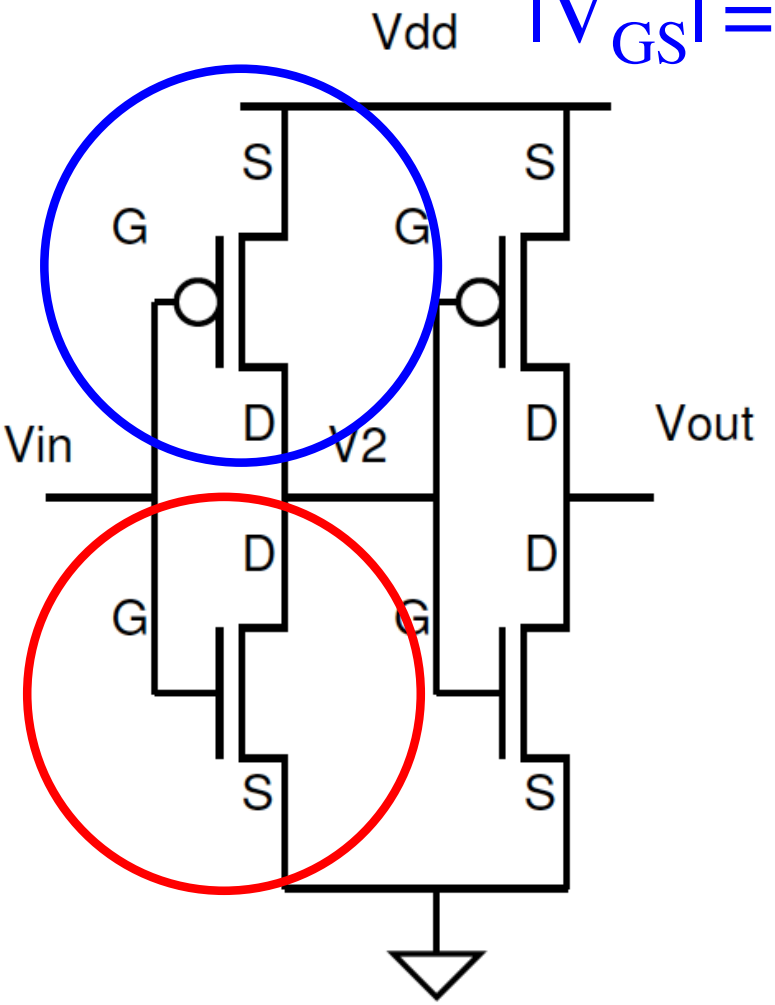

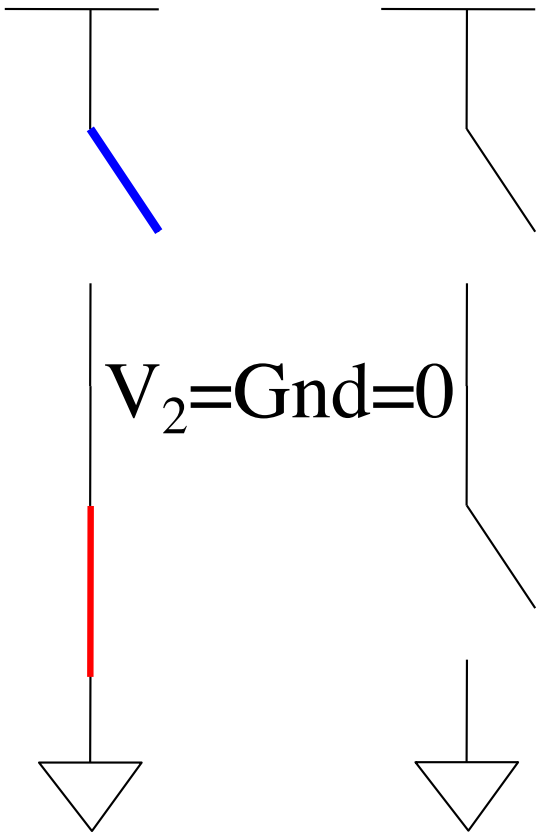

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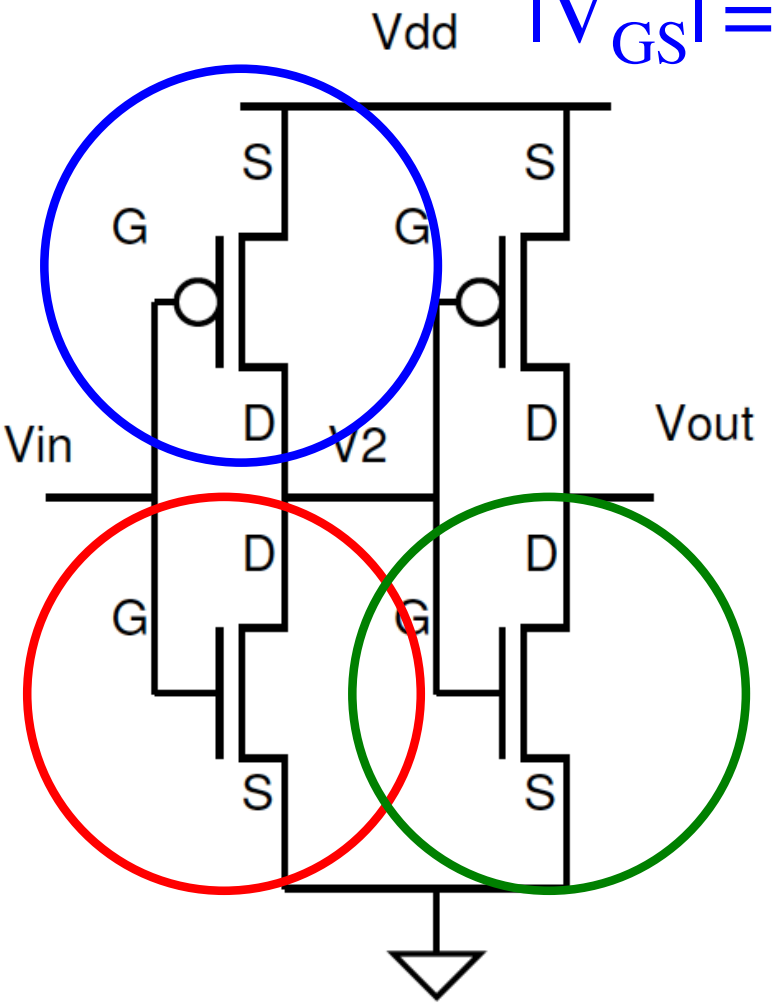

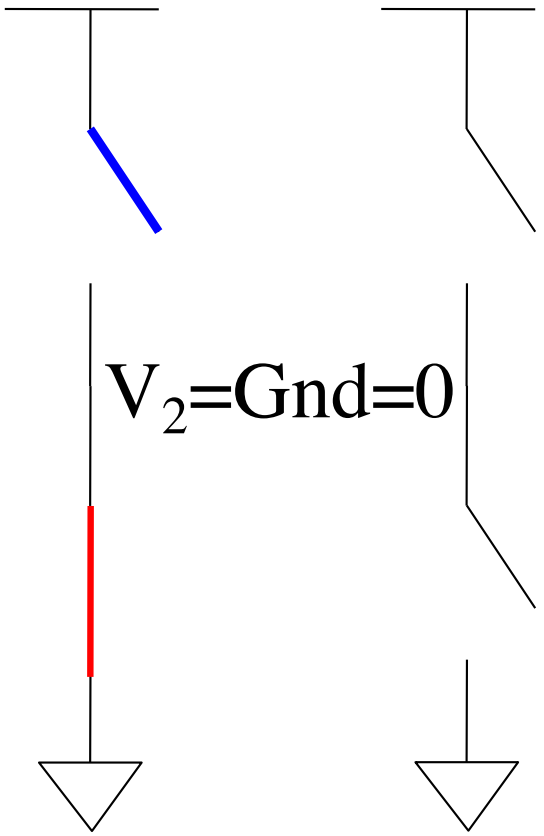

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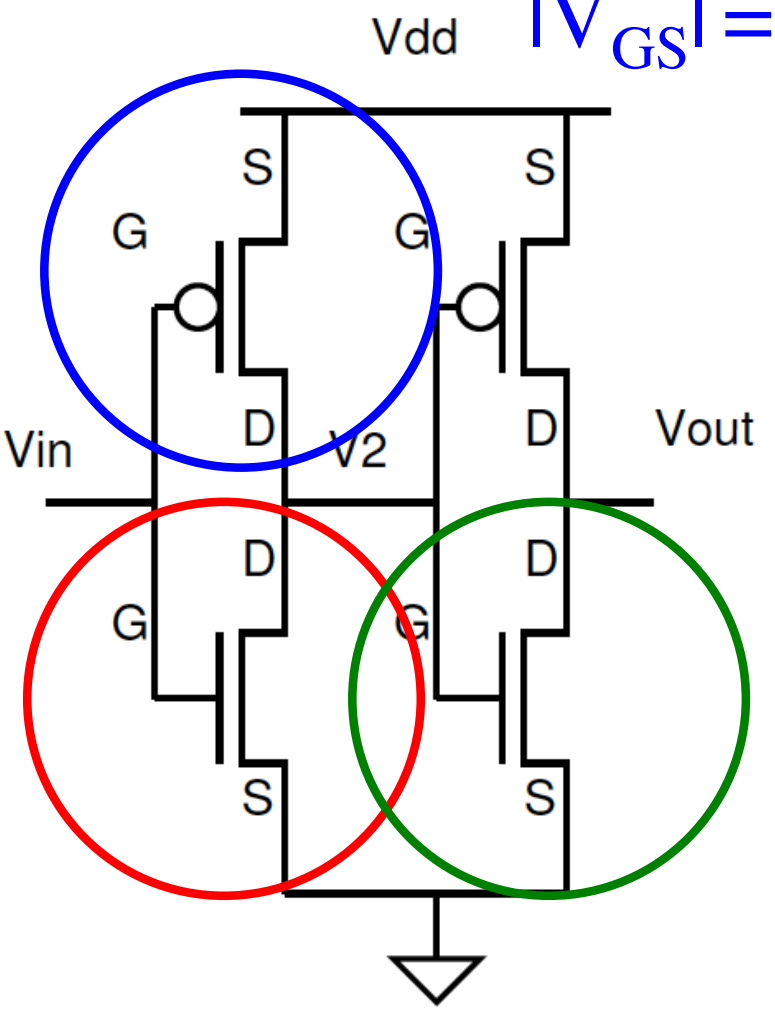

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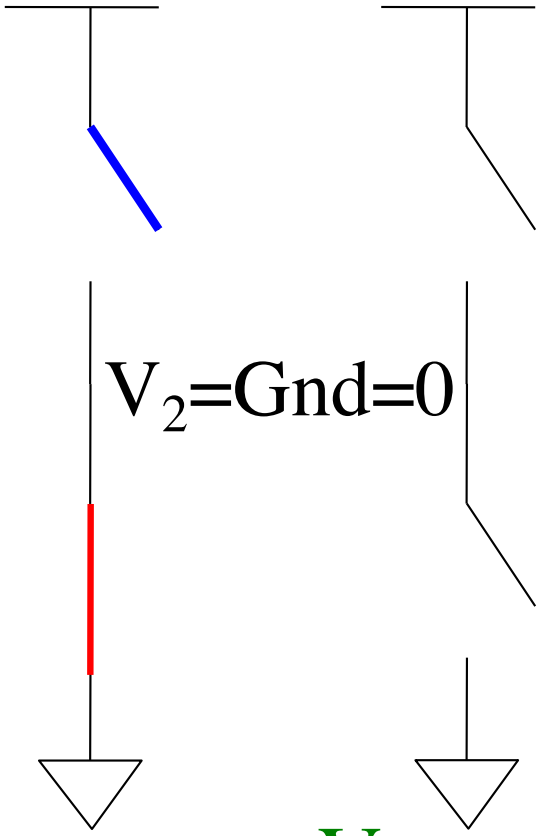

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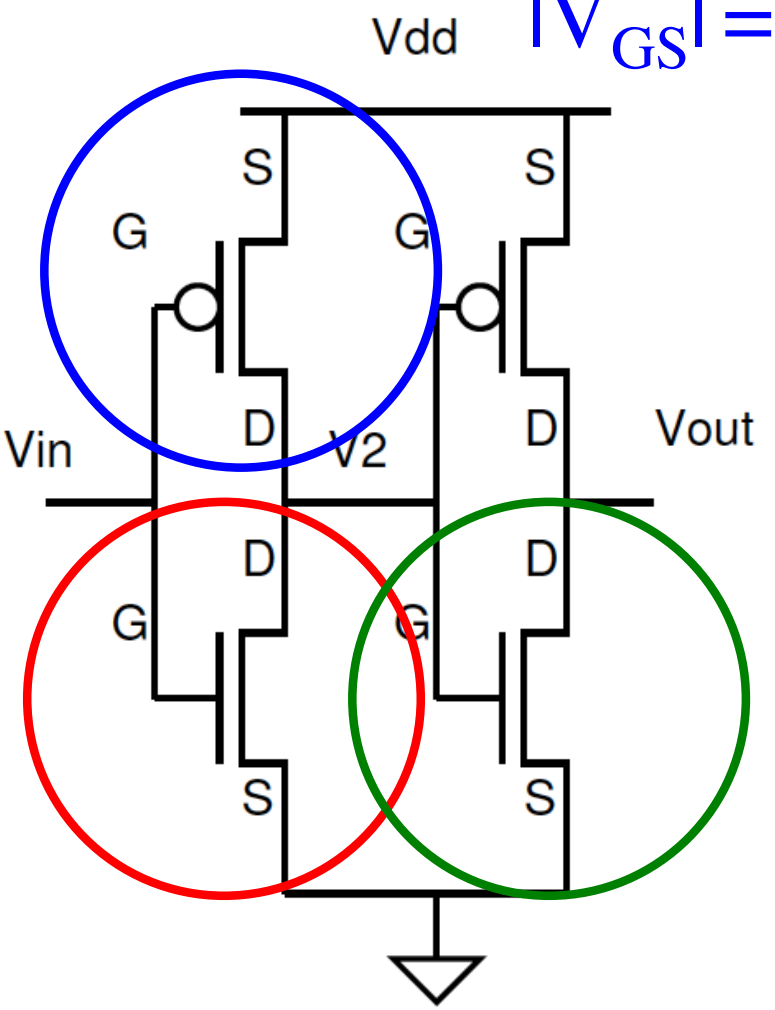

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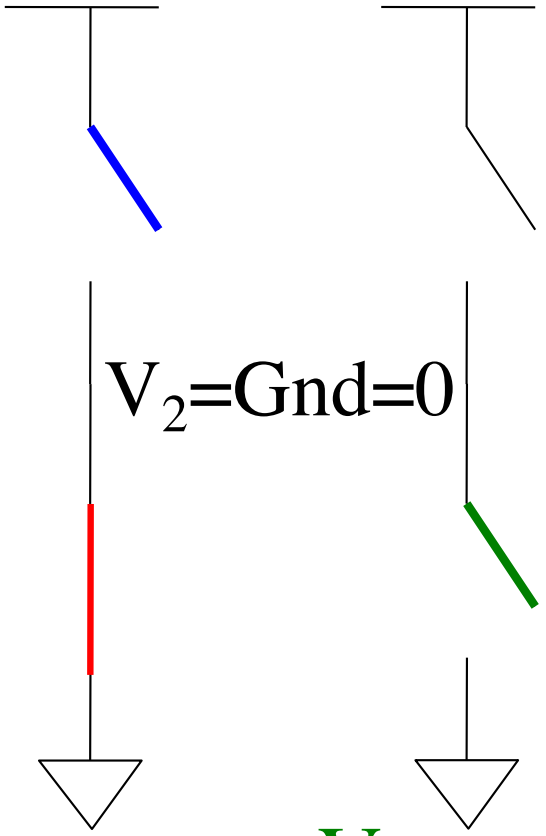

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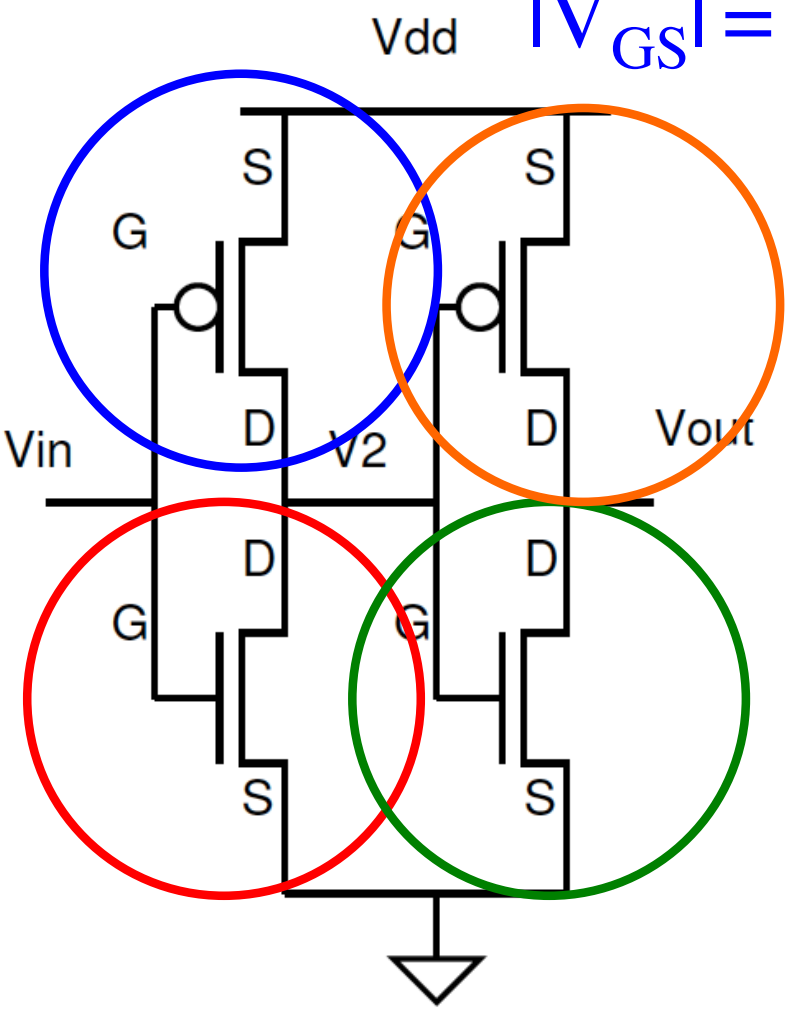

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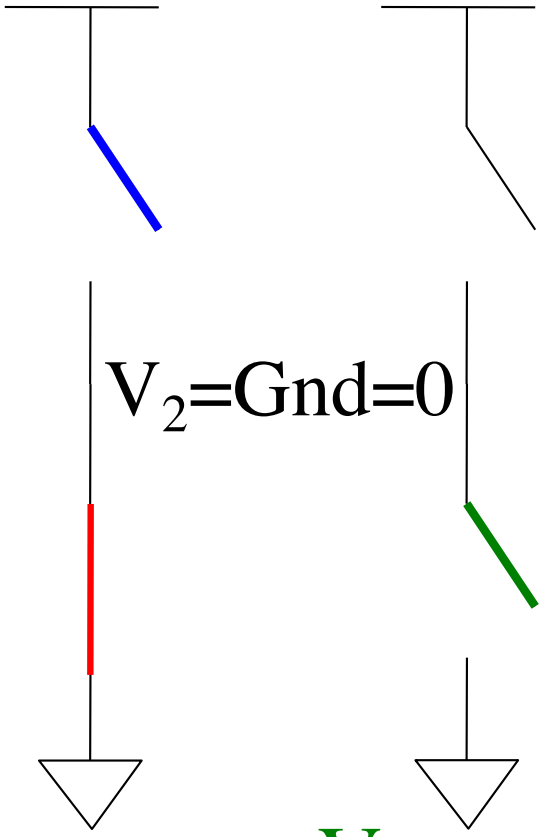

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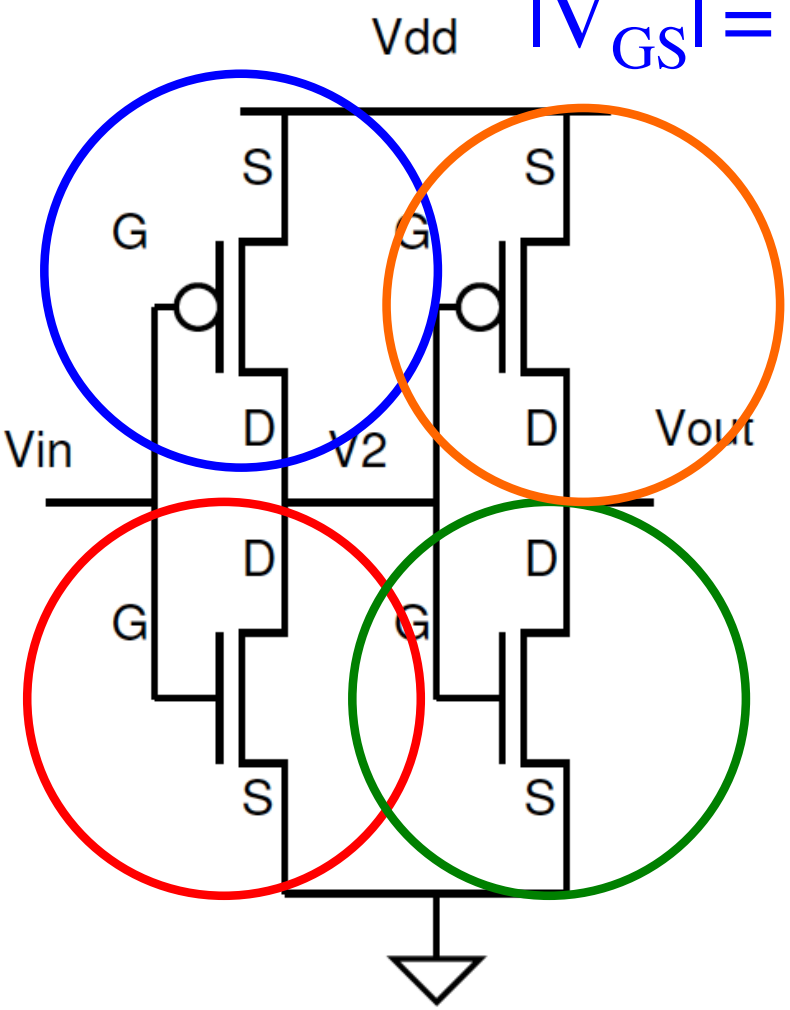
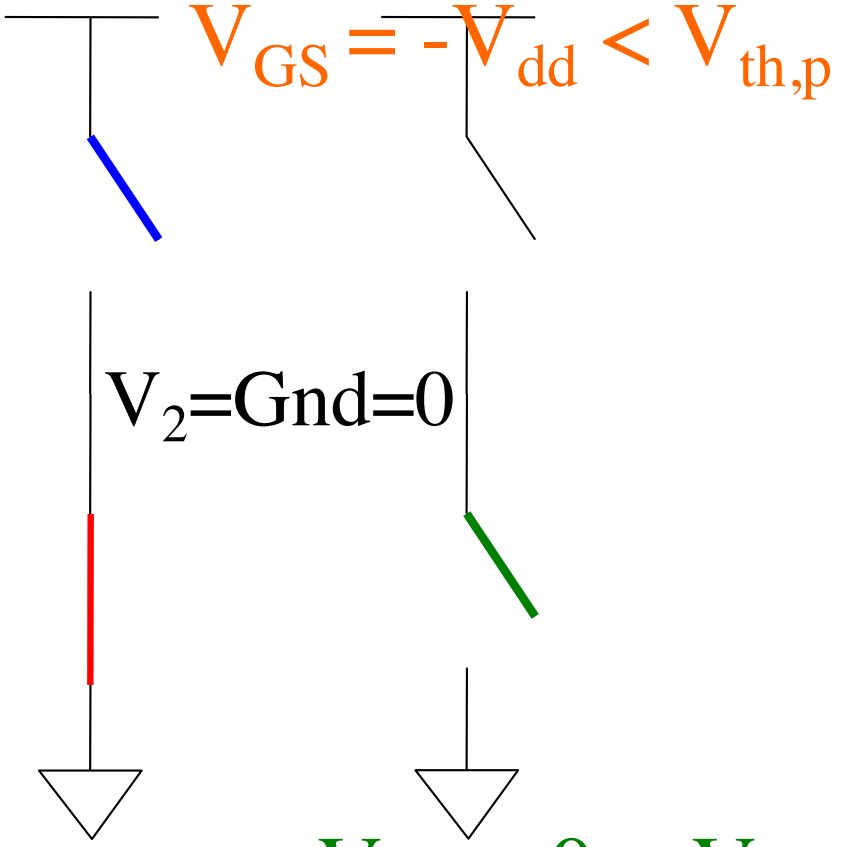


$|V_{GS}| = 0 < |V_{th,p}|$



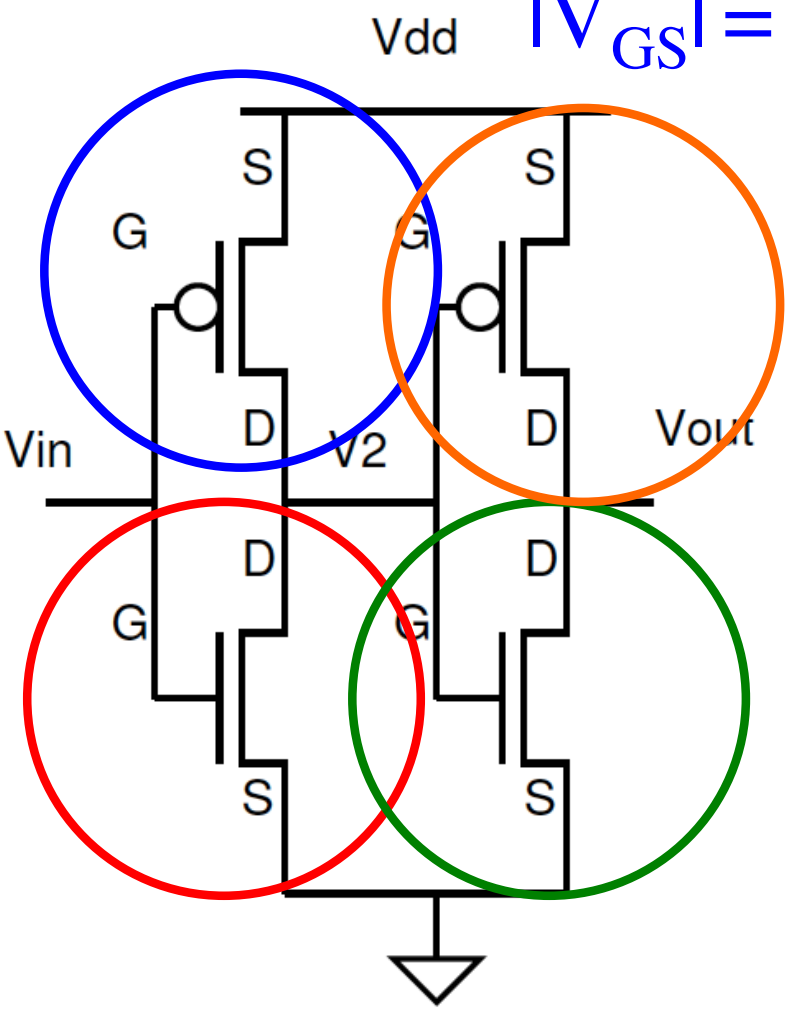
$V_{GS} = V_G - V_S = V_{dd} > V_{th,n}$

Apply zero-order model?

What happens when $V_{in} = V_{dd} > V_{thn}$?

$V_{th,p} = -V_{th,n}$

$V_{GS} = V_G - V_S$



$|V_{GS}| = 0 < |V_{th,p}|$

$V_{GS} = -V_{dd} < V_{th,p}$

$|V_{GS}| = V_{dd} > |V_{th,p}|$

V_2=Gnd=0

$V_{GS} = 0 < V_{th,n}$

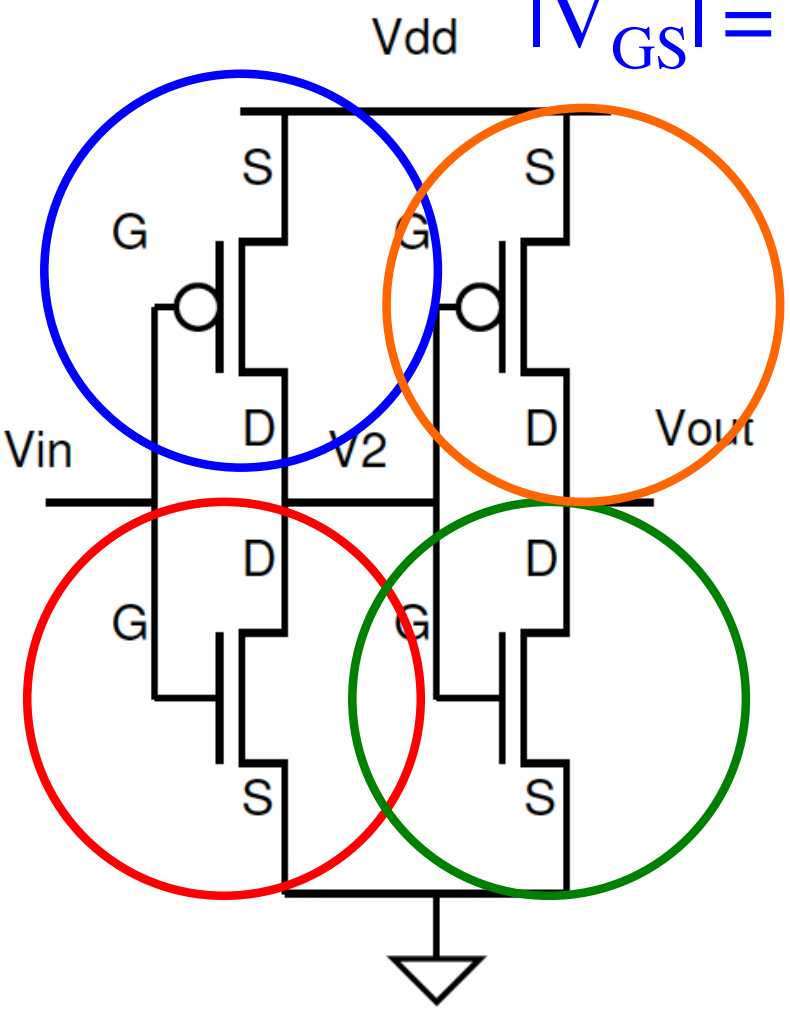
$V_{GS} = V_G - V_S = V_{dd} > V_{th,n}$

Apply zero-order model?

What happens when $V_{in} = V_{dd} > V_{thn}$?

$V_{th,p} = -V_{th,n}$

$V_{GS} = V_G - V_S$



$|V_{GS}| = 0 < |V_{th,p}|$

$V_{GS} = -V_{dd} < V_{th,p}$

V_2=Gnd=0

$V_{out} = V_{dd}$

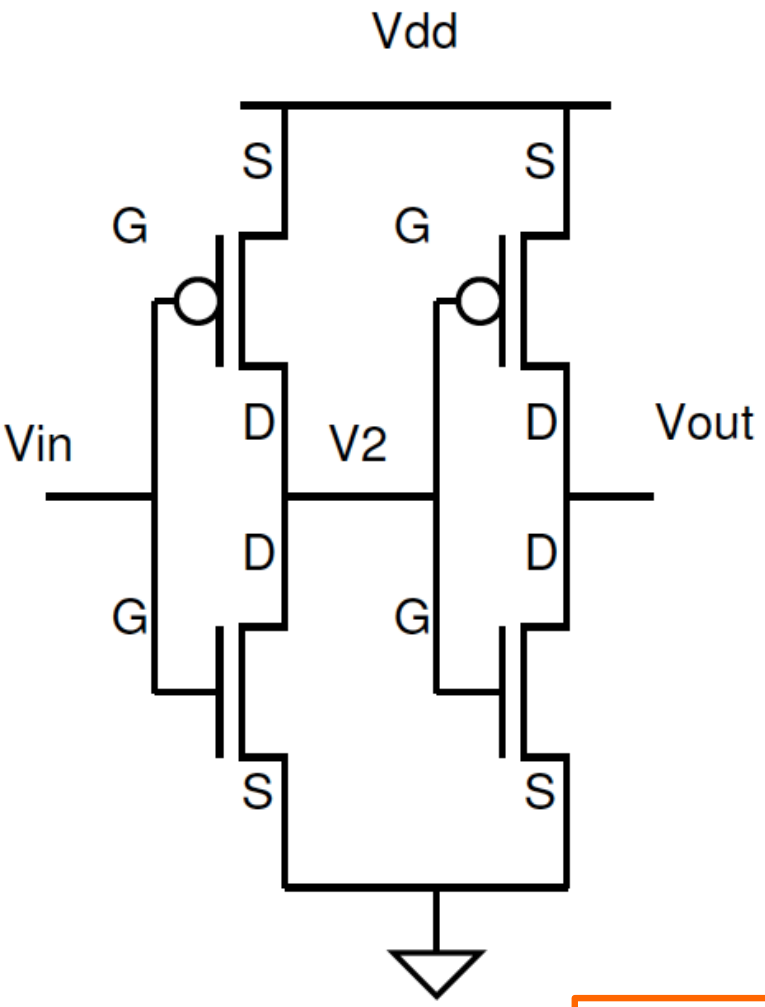
$V_{GS} = 0 < V_{th,n}$

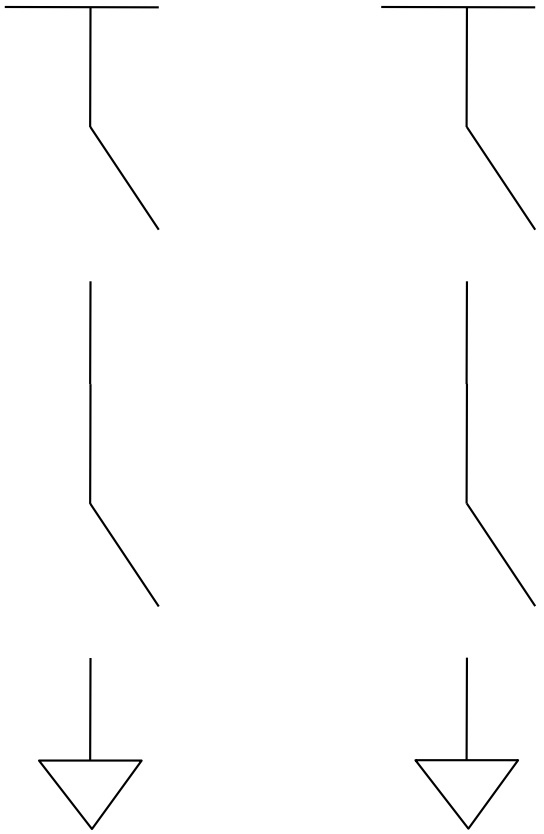
$V_{GS} = V_G - V_S = V_{dd} > V_{th,n}$

Apply zero-order model?

What happens when $V_{in} = 0$?

$V_{th,p} = -V_{th,n}$
$V_{GS} = V_G - V_S$



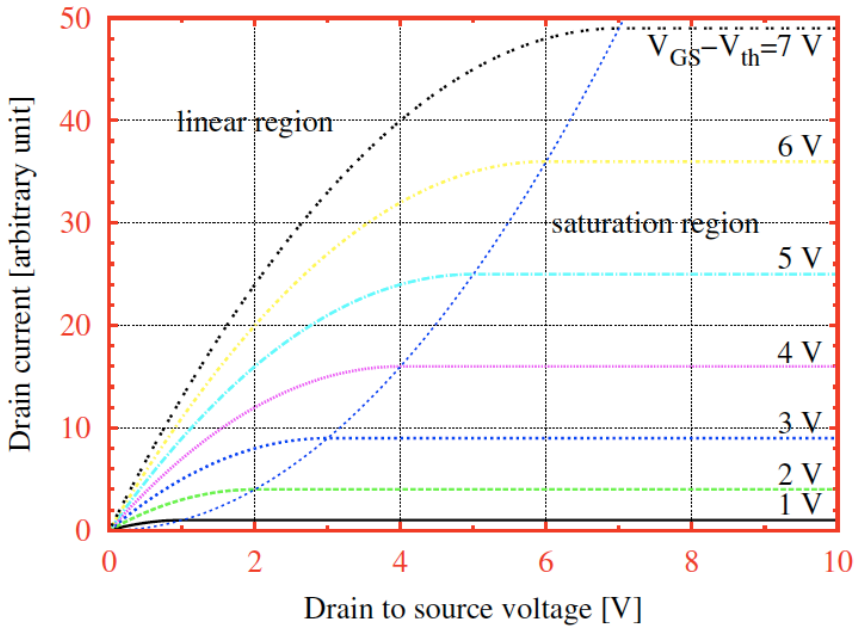


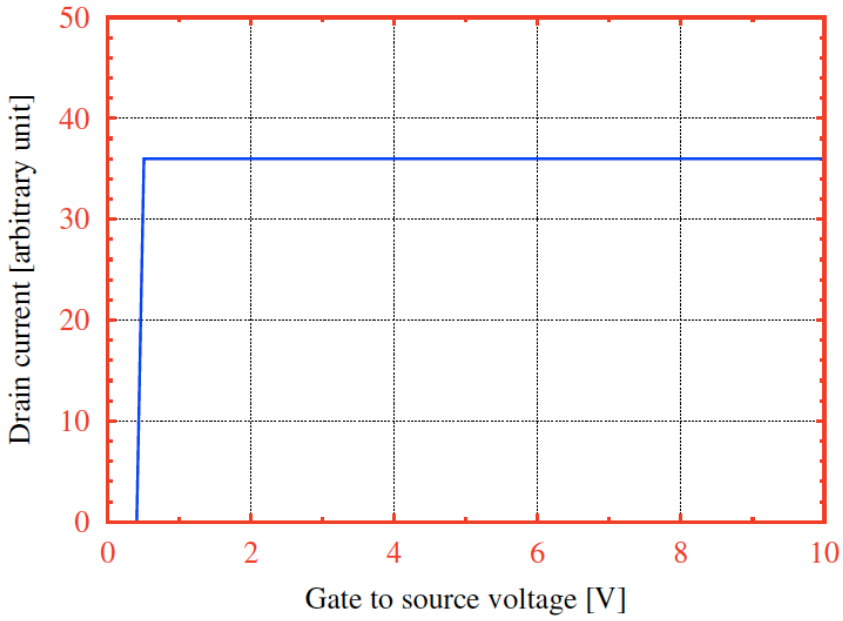
Convince yourself that $V_{out} = 0$.

Zeroeth Order Model

- Allows us to reason (mostly) at logic level about steady-state functionality of typical gate circuits before worrying about performance (speed, power, etc.) details

What is missing in Zeroeth Order Model?



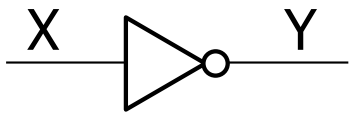


- Delay
  - Parasitic capacitances and resistances
- Dynamics
- Zeroeth Order captures behaviour if our circuit is not:
  - Capacitively loaded, acyclic (if there are Loops)

Digital Logic

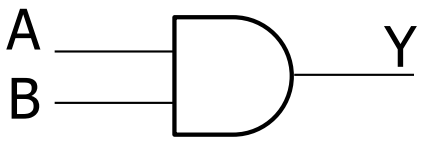
Basic Digital Gates

NOT
$Y = \overline{X}$



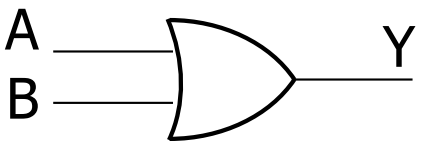
X	Y
0	1
1	0

AND
$Y = A \bullet B$



A	B	Y
0	0	0
0	1	0
1	0	0
1	1	1

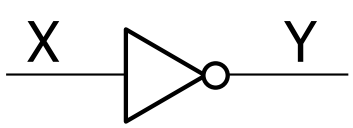
OR
$Y = A + B$



A	B	Y
0	0	0
0	1	1
1	0	1
1	1	1

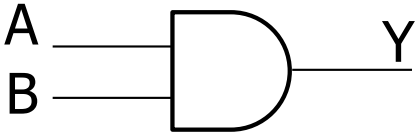
Basic Digital Gates

NOT
$Y = \overline{X}$



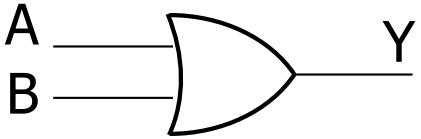
X	Y
0	1
1	0

AND
$Y = A \bullet B$



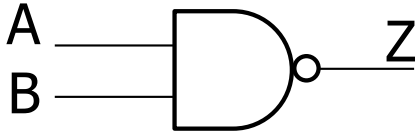
A	B	Y	Z
0	0	0	1
0	1	0	1
1	0	0	1
1	1	1	0

OR
$Y = A + B$

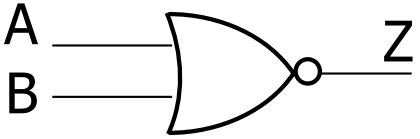


A	B	Y	Z
0	0	0	1
0	1	1	0
1	0	1	0
1	1	1	0

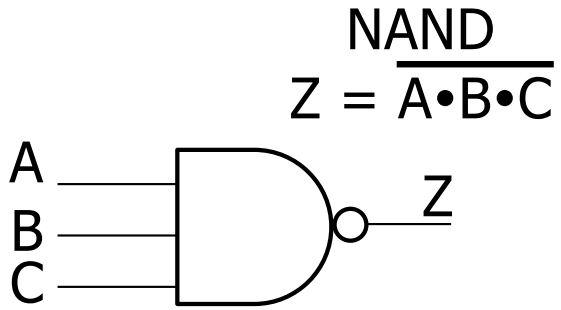
NAND
$Z = \overline{A \bullet B}$



NOR
$Z = \overline{A + B}$



Basic Digital Gates



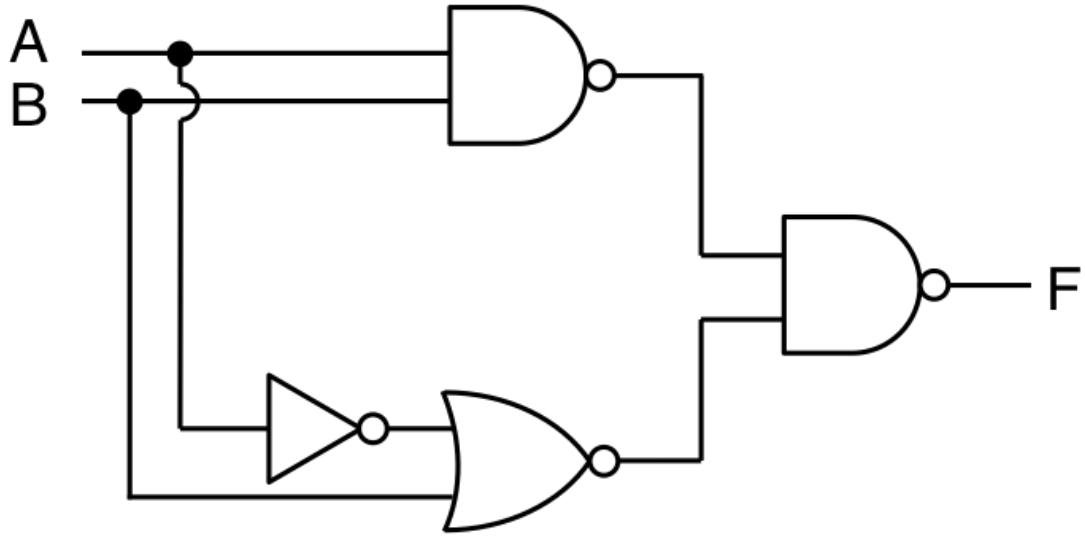
A	B	C	Z
0	0	0	1
0	0	1	1
0	1	0	1
0	1	1	1
1	0	0	1
1	0	1	1
1	1	0	1
1	1	1	0

Boolean Algebra

TABLE 2-3
Basic Identities of Boolean Algebra

1.	$X+0=X$	2.	$X\cdot 1=X$	
3.	$X+1=1$	4.	$X\cdot 0=0$	
5.	$X+X=X$	6.	$X\cdot X=X$	
7.	$X+\overline{X}=1$	8.	$X\cdot\overline{X}=0$	
9.	$\overline{\overline{X}}=X$			
10.	$X+Y=Y+X$	11.	$XY=YX$	Commutative
12.	$X+(Y+Z)=(X+Y)+Z$	13.	$X(YZ)=(XY)Z$	Associative
14.	$X(Y+Z)=XY+XZ$	15.	$X+YZ=(X+Y)(X+Z)$	Distributive
16.	$\overline{X+Y}=\overline{X}\cdot\overline{Y}$	17.	$\overline{X\cdot Y}=\overline{X}+\overline{Y}$	DeMorgan's

Combination



Boolean Expressions

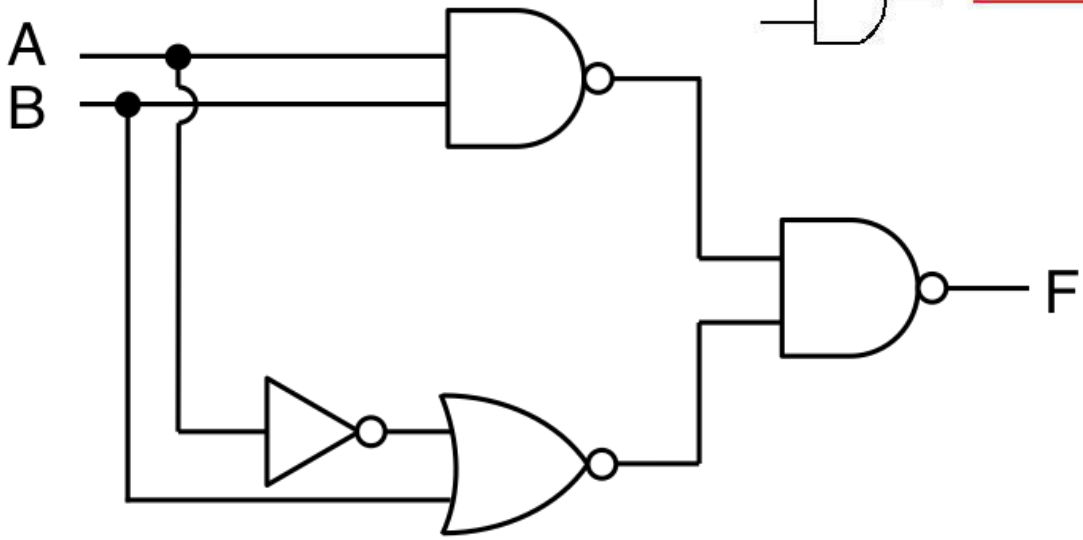
- Sum-of-products form (SOP)
  - Eg. ABC+DEF+GHI
- Product-of-sums form (POS)
  - Eg. (A+B+C)(D+E+F)(G+H+I)

- Convert between the two with Boolean algebra
  - DeMorgan's Law

$$A + B = \overline{\overline{A} \cdot \overline{B}}$$

$$A \cdot B = \overline{\overline{A} + \overline{B}}$$

Combination



Canonical Form

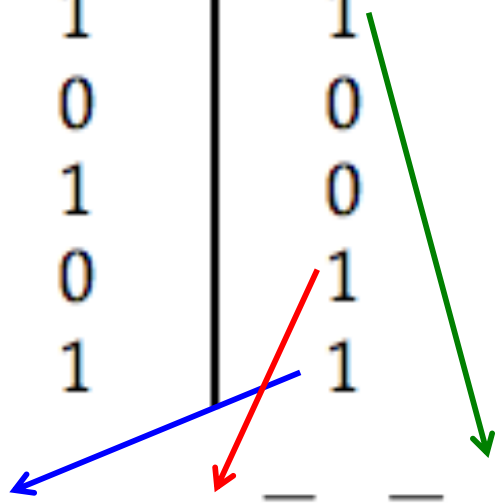
- Every minterm in your expression has every variable

Row Number	A	B	C	f
0	0	0	0	0
1	0	0	1	0
2	0	1	0	0
3	0	1	1	1
4	1	0	0	0
5	1	0	1	0
6	1	1	0	1
7	1	1	1	1

Canonical Form

- Every minterm in your expression has every variable

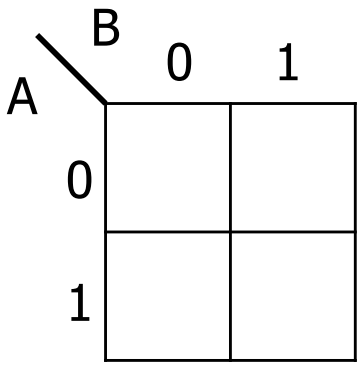
Row Number	A	B	C	f
0	0	0	0	0
1	0	0	1	0
2	0	1	0	0
3	0	1	1	1
4	1	0	0	0
5	1	0	1	0
6	1	1	0	1
7	1	1	1	1

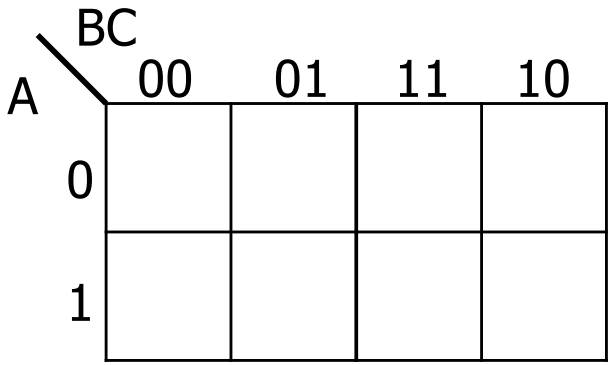


$$f(A,B,C) = ABC + AB\overline{C} + \overline{A}BC$$

What is a K(arnaugh)-map?

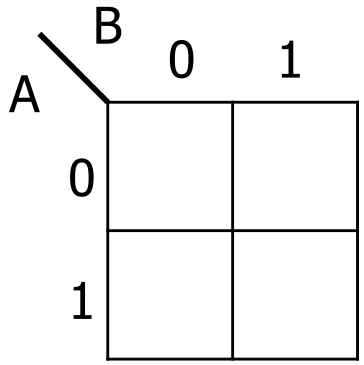
- A grid of squares (representing truth table)
- Each square represents one minterm
- The minterms are ordered according to **Gray code**
  - Only one variable changes between adjacent squares
- Squares on edges are considered adjacent to squares on opposite edges
  - I.e Table wraps around
- K-maps are clumsy with more than 4 variables





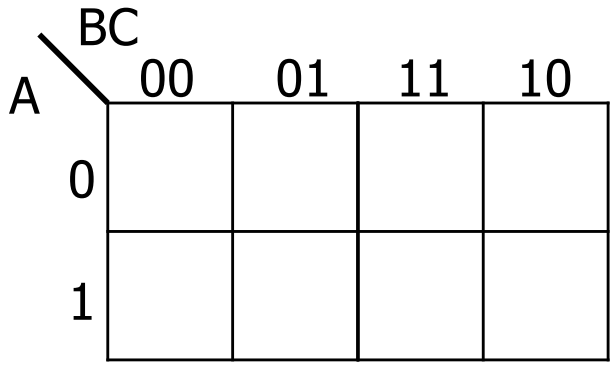
K-map Examples (Preclass 1)

- 2-variable



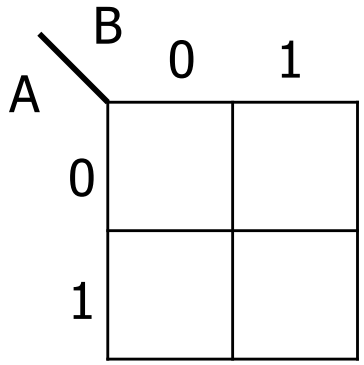
Eg: Z = A′B′ + AB′ + A′B

- 3-variable



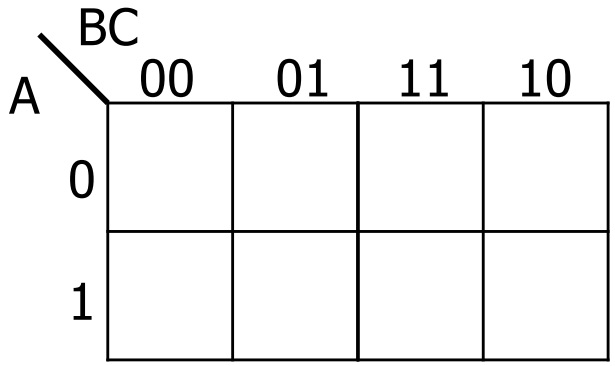
K-map Examples (Preclass 2)

- 2-variable



Eg: Z = A′B′ + AB′ + A′B

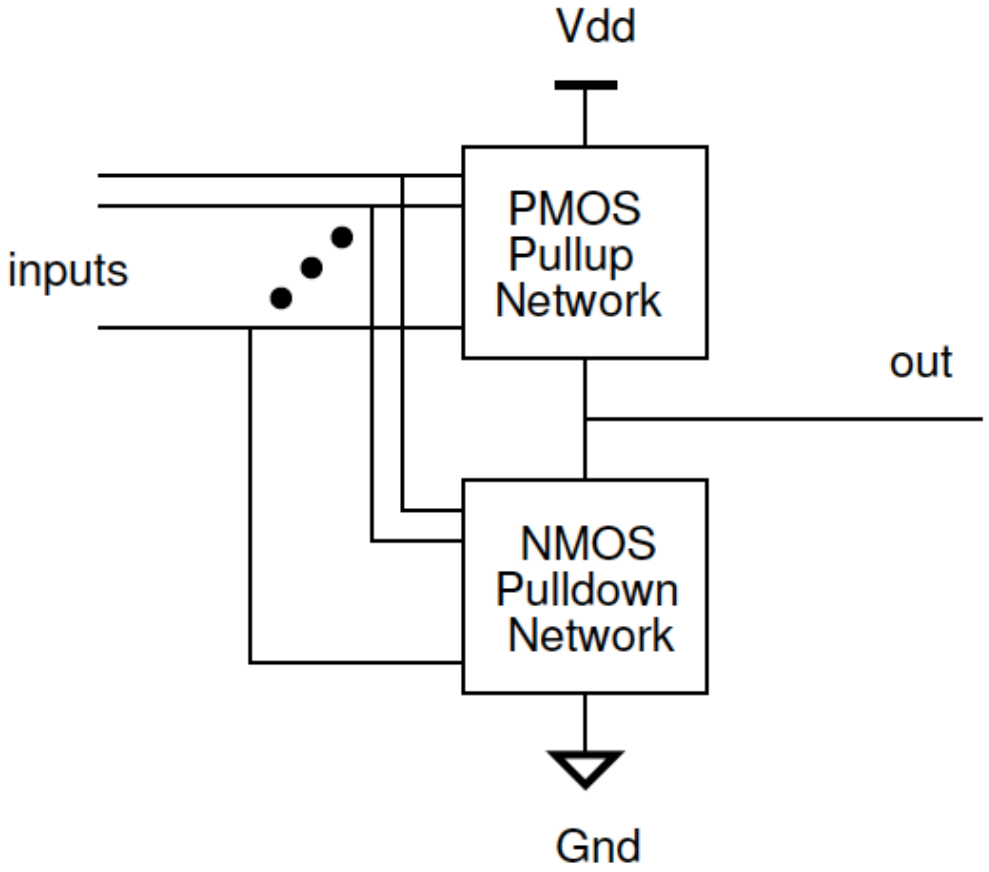
- 3-variable



Eg: Z = A′B′C′ + A′B + ABC′ + AC

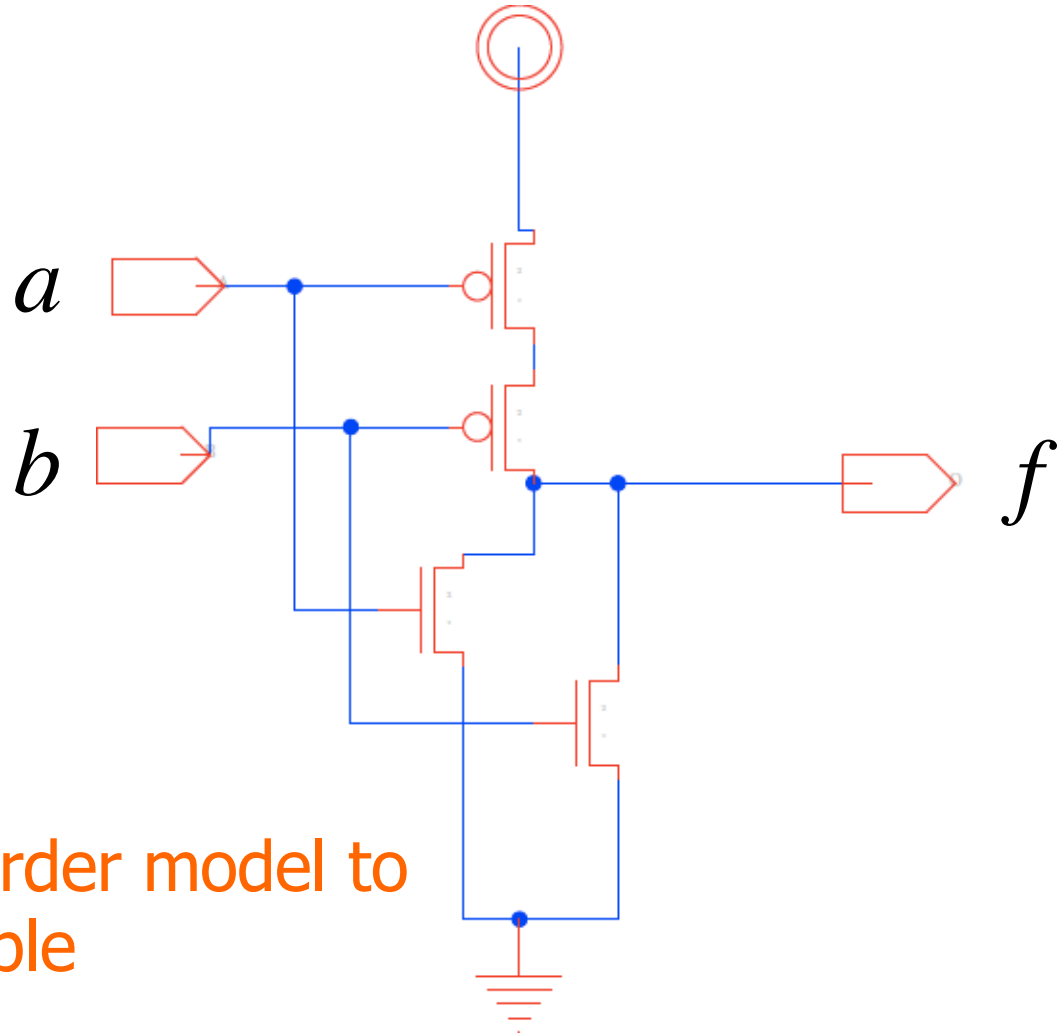
CMOS Gates

How to construct static CMOS gates



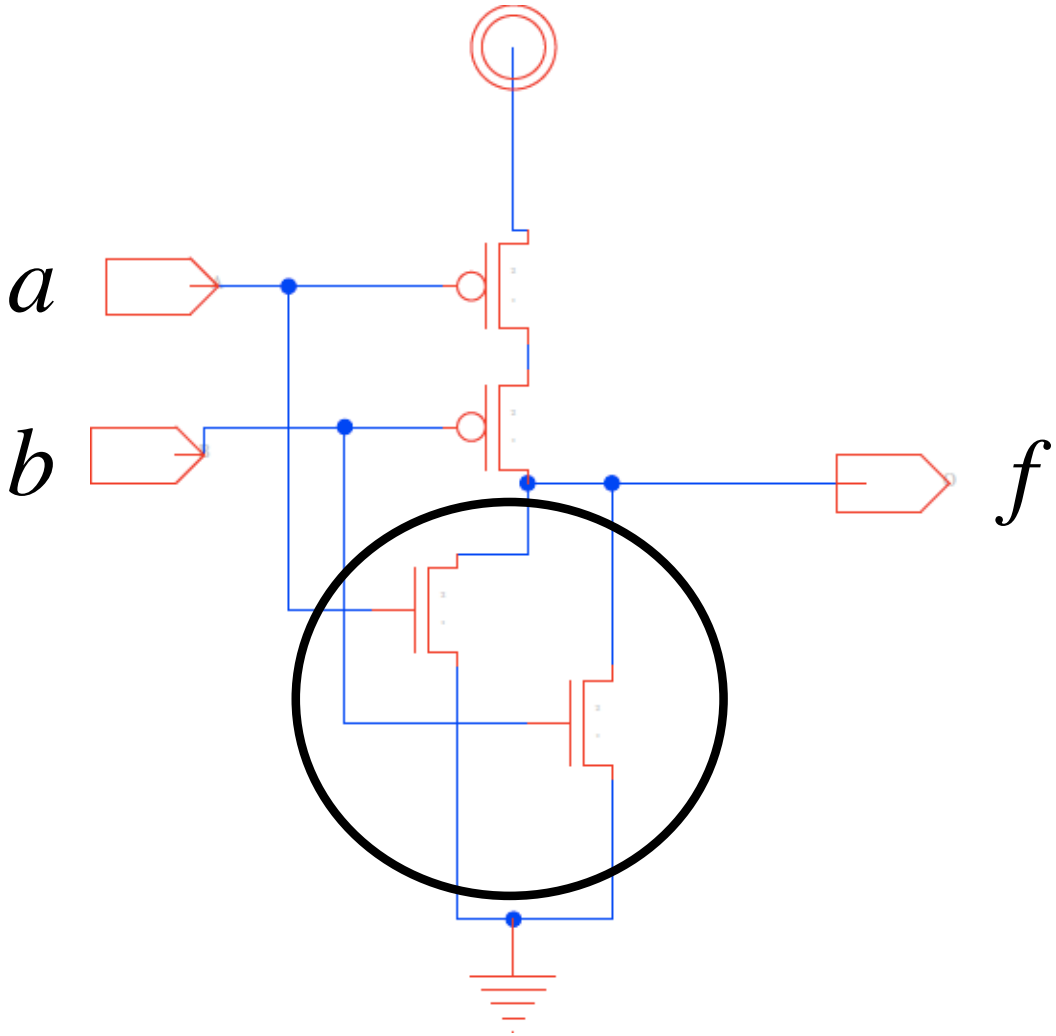
- Complementary Metal Oxide Semiconductor

What gate is this? Preclass 3

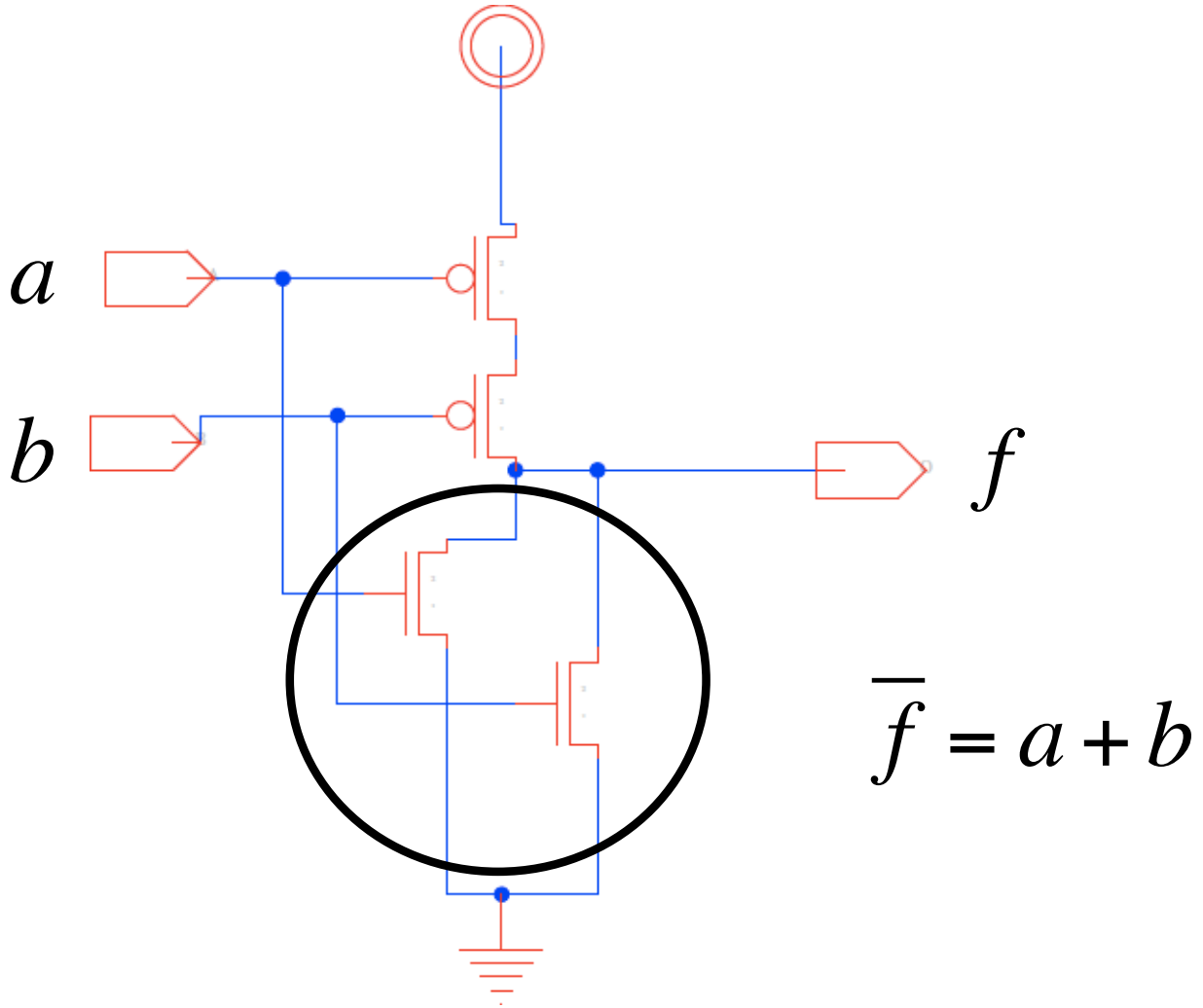


Hint: use zero order model to make a truth table

What gate is this?



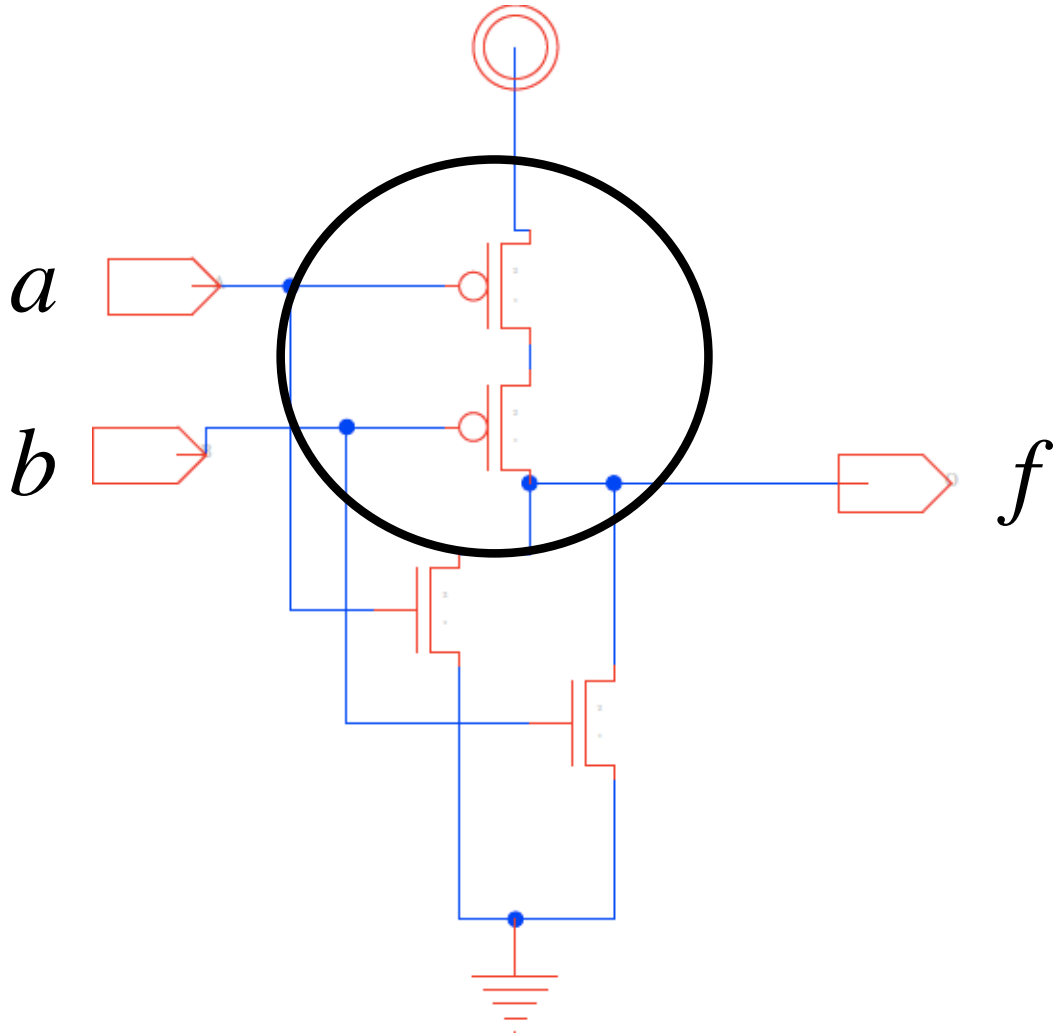
What gate is this? Preclass 4



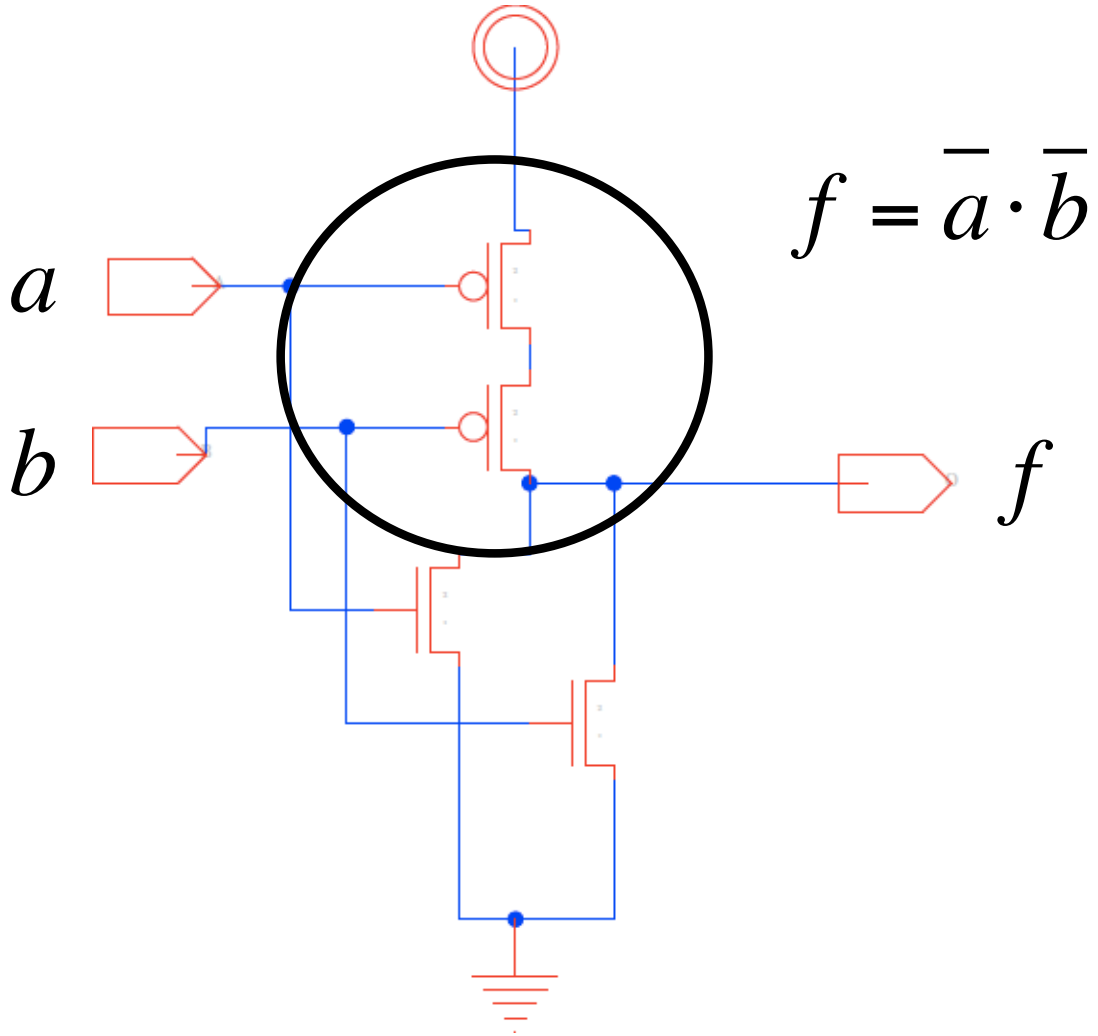
$$\overline{f} = a + b$$

What is f in minimum-sum-of-products form?

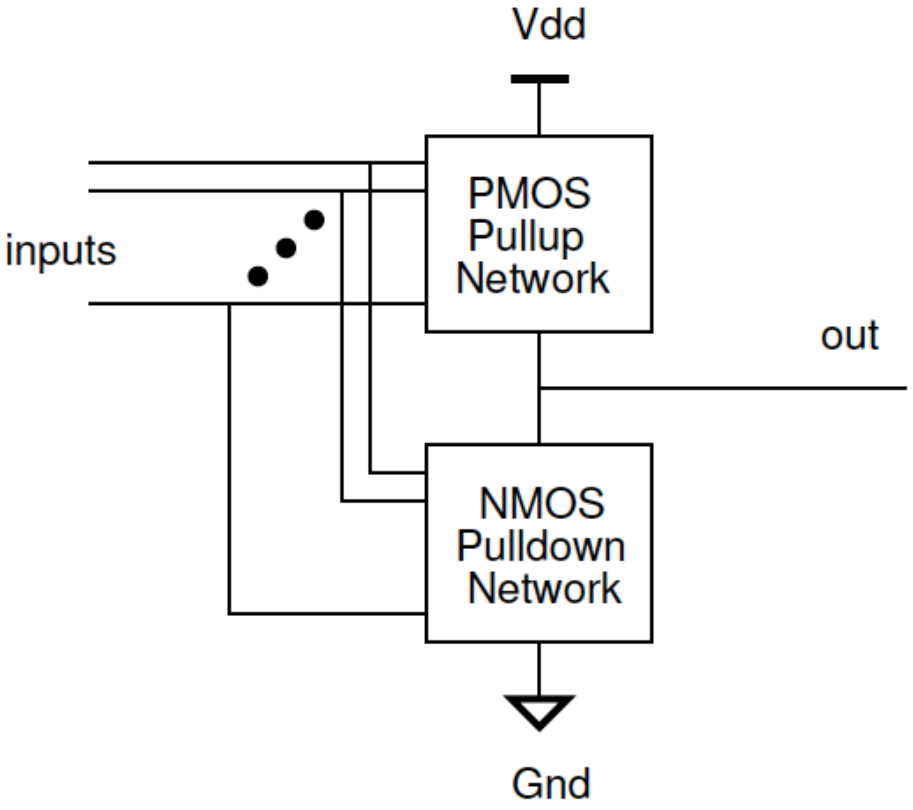
What gate is this?

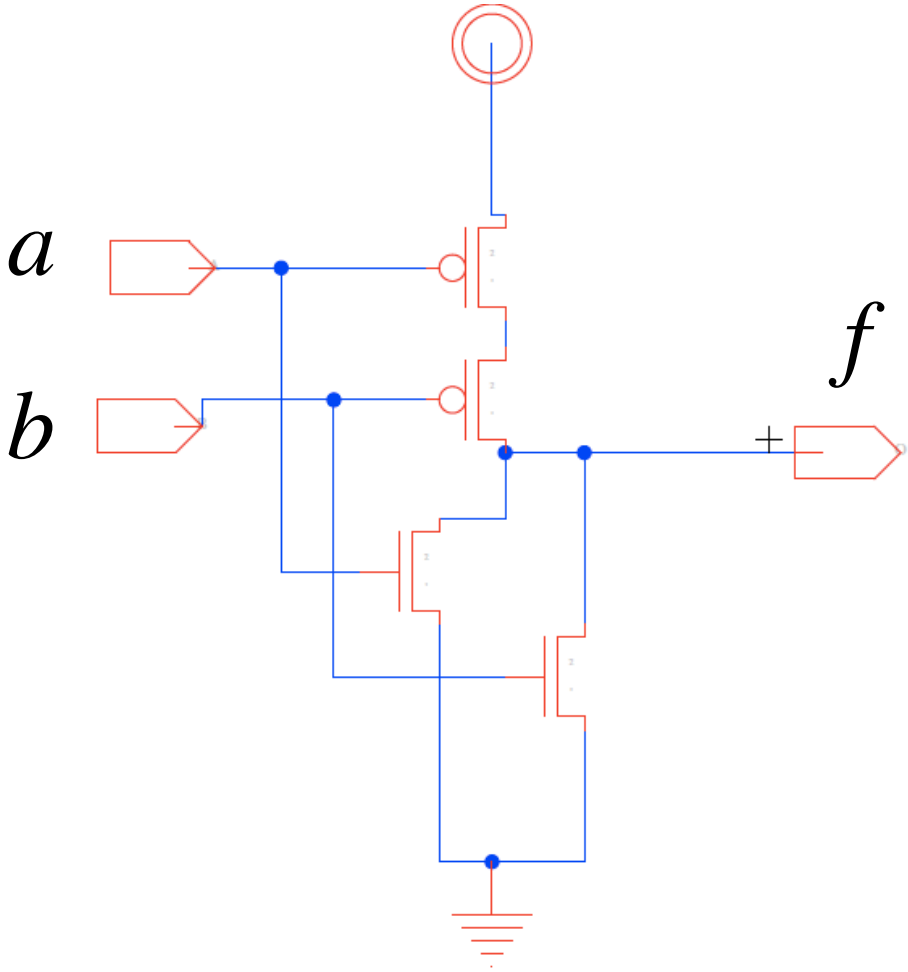


What gate is this?



Static CMOS Gate Structure

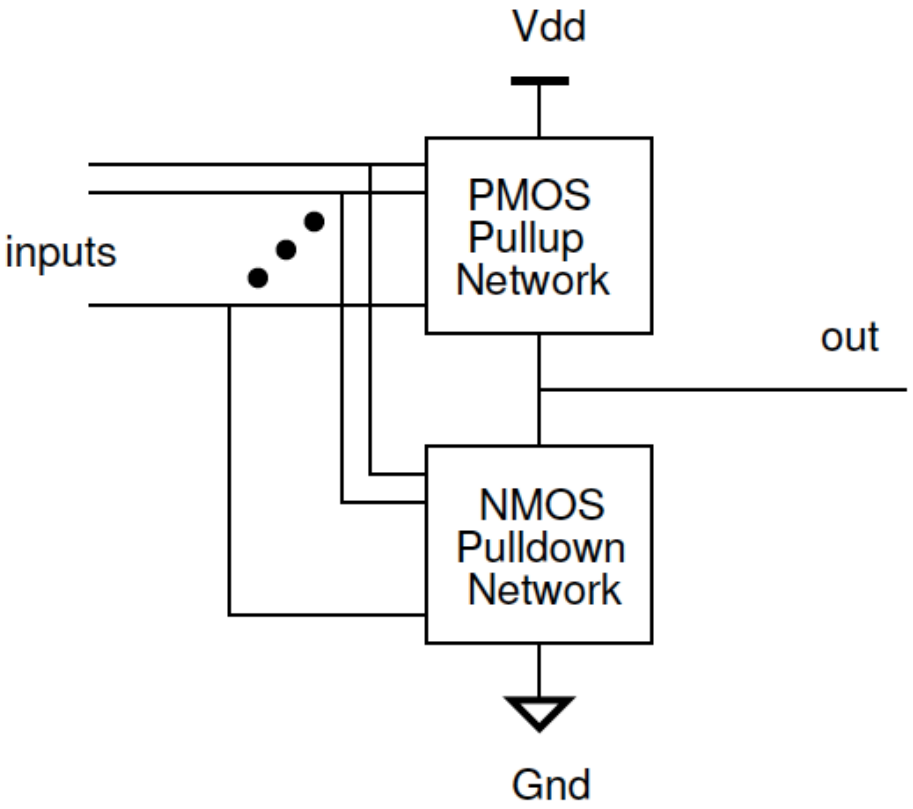




CMOS

- Complementary Metal Oxide Semicondutor
- Uses *complementary* transistors
  - NMOS, PMOS
- Pull-down and pull-up networks are *complements* of each other
  - Only one network active (on) at a time to charge or discharge output to V_{dd} or Gnd respectively

Static CMOS Gate Structure

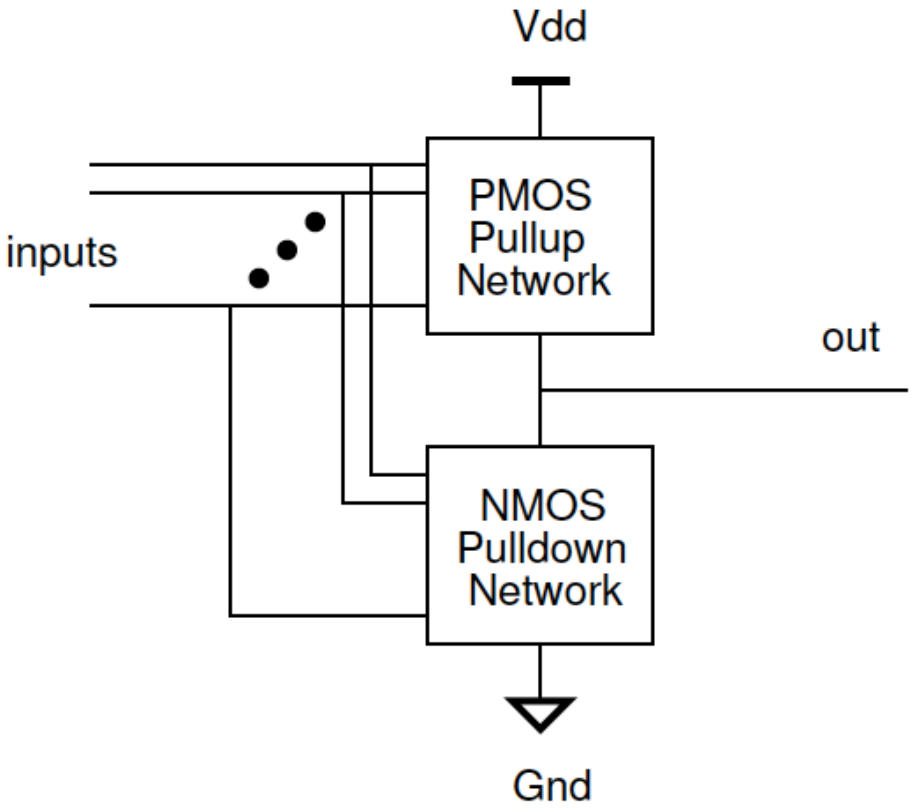


- Drives rail-to-rail
  - Power rails are V_{dd} and Gnd
  - output is V_{dd} or Gnd
- Input connects to gates → load is capacitive
- Once output node is charged doesn't use energy (no static current)
- Output actively driven

Gate Design Example Preclass 5

- Design gate to perform: $f = (\overline{a} + \overline{b}) \cdot \overline{c}$

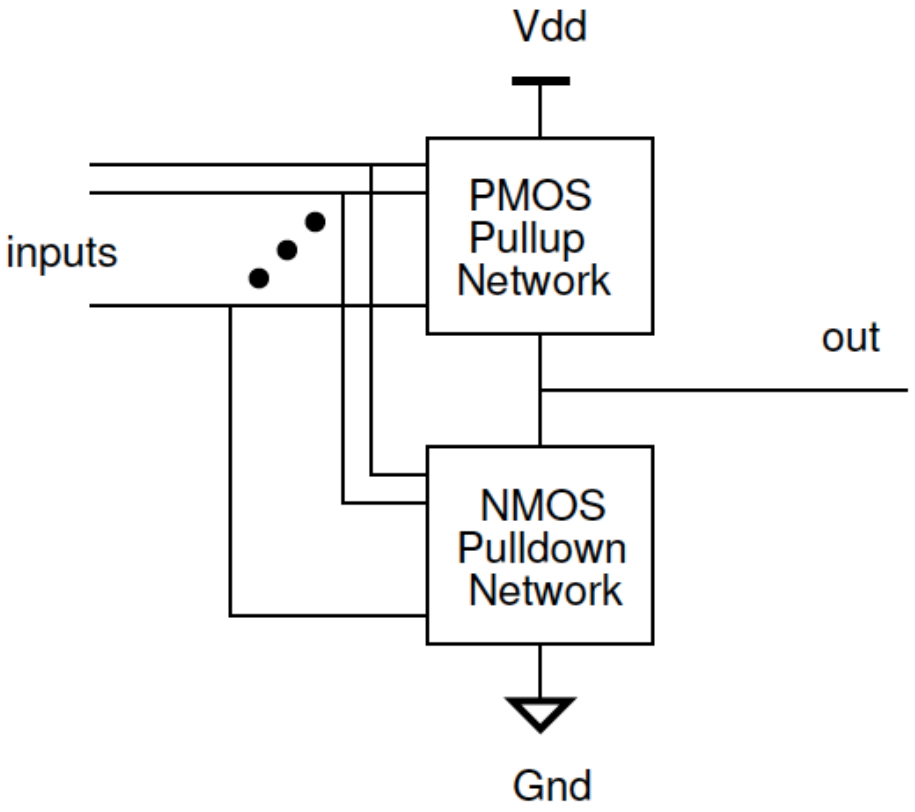
- Strategy:
  1. Use static CMOS structure
  2. Design PMOS pullup for *f*
  3. Use DeMorgan's Law to determine *f'*
  4. Design NMOS pulldown for *f'*



Gate Design Example

- Design gate to perform: $f = (\overline{a} + \overline{b}) \cdot \overline{c}$

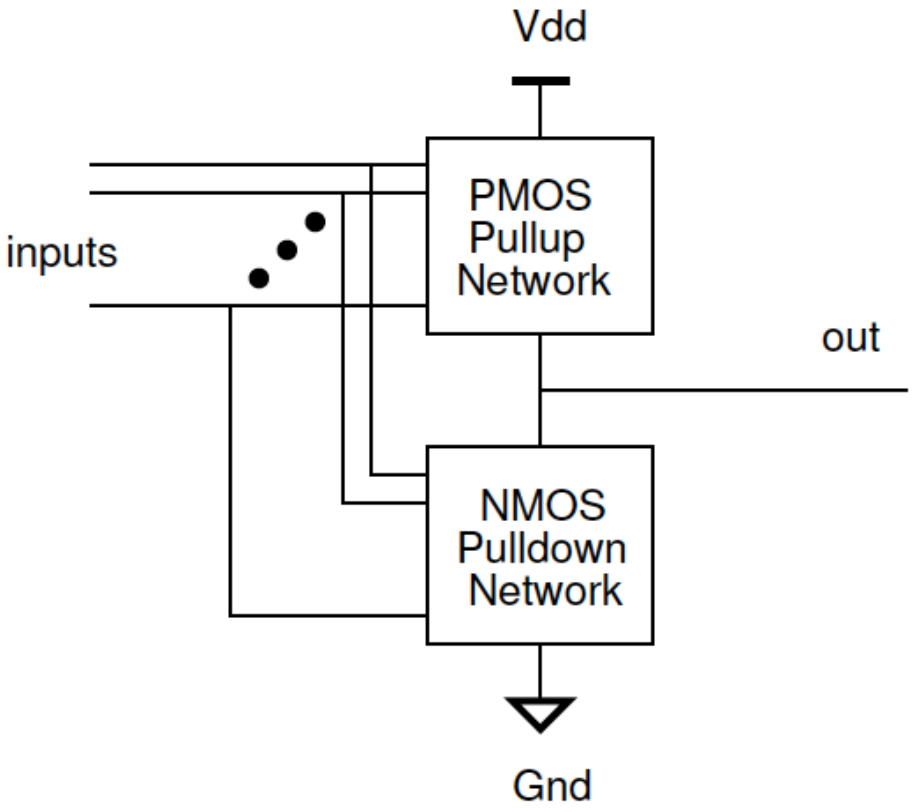
- PMOS Pullup for *f*?



Gate Design Example

- Design gate to perform: $f = (\overline{a} + \overline{b}) \cdot \overline{c}$

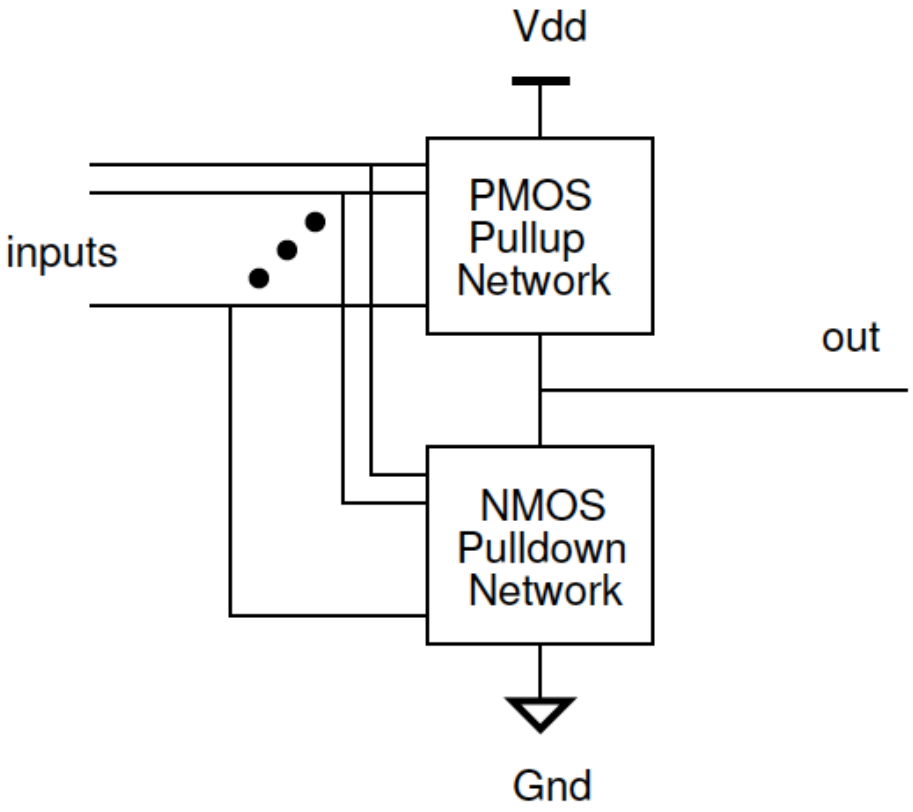
- What is *f'*?
  - DeMorgan's Law



Gate Design Example

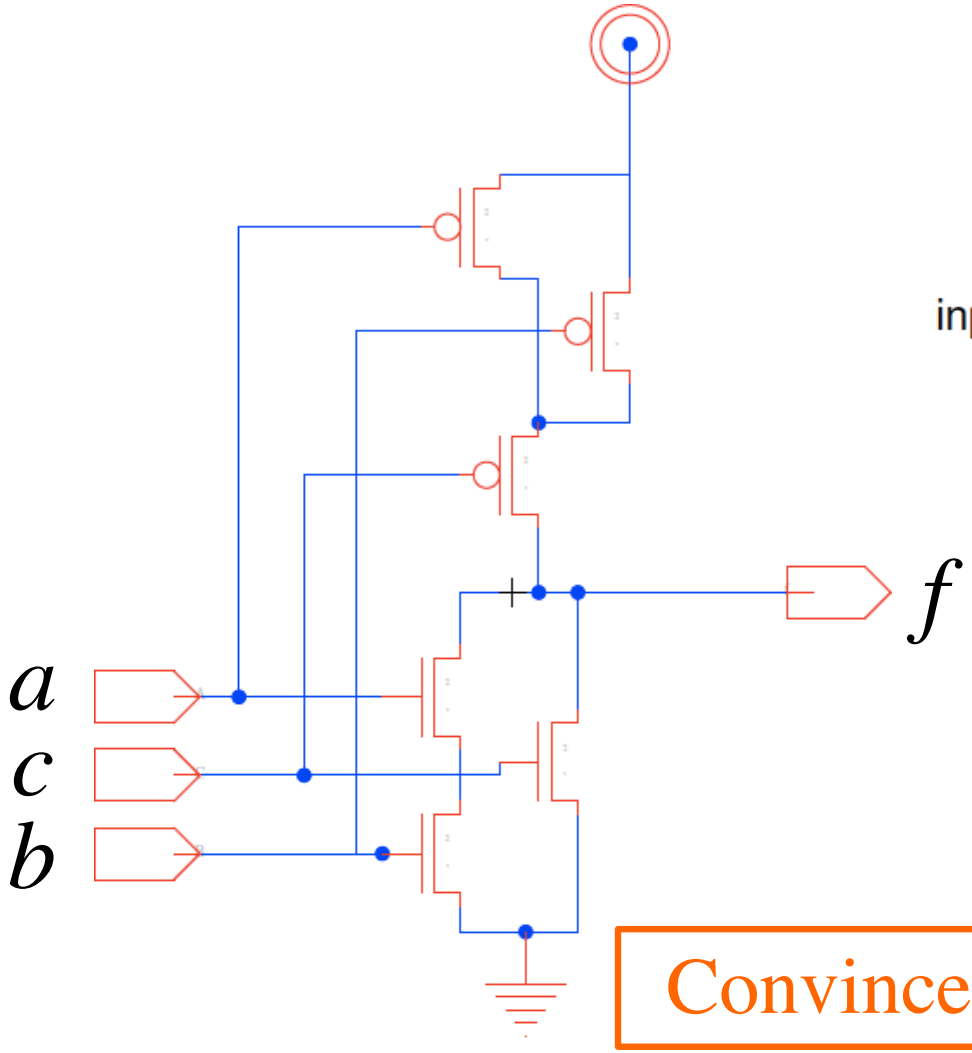
- Design gate to perform: $f = (\overline{a} + \overline{b}) \cdot \overline{c}$

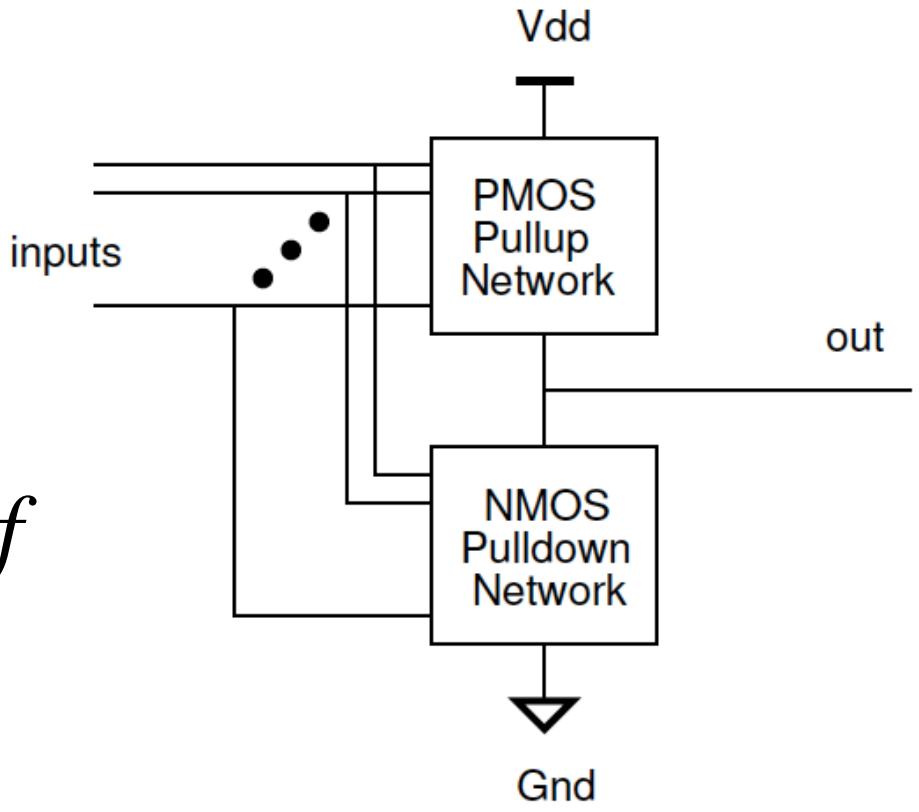
- Design NMOS pulldown for *f'*



Gate Design Example

- Design gate to perform: $f = (\overline{a} + \overline{b}) \cdot \overline{c}$

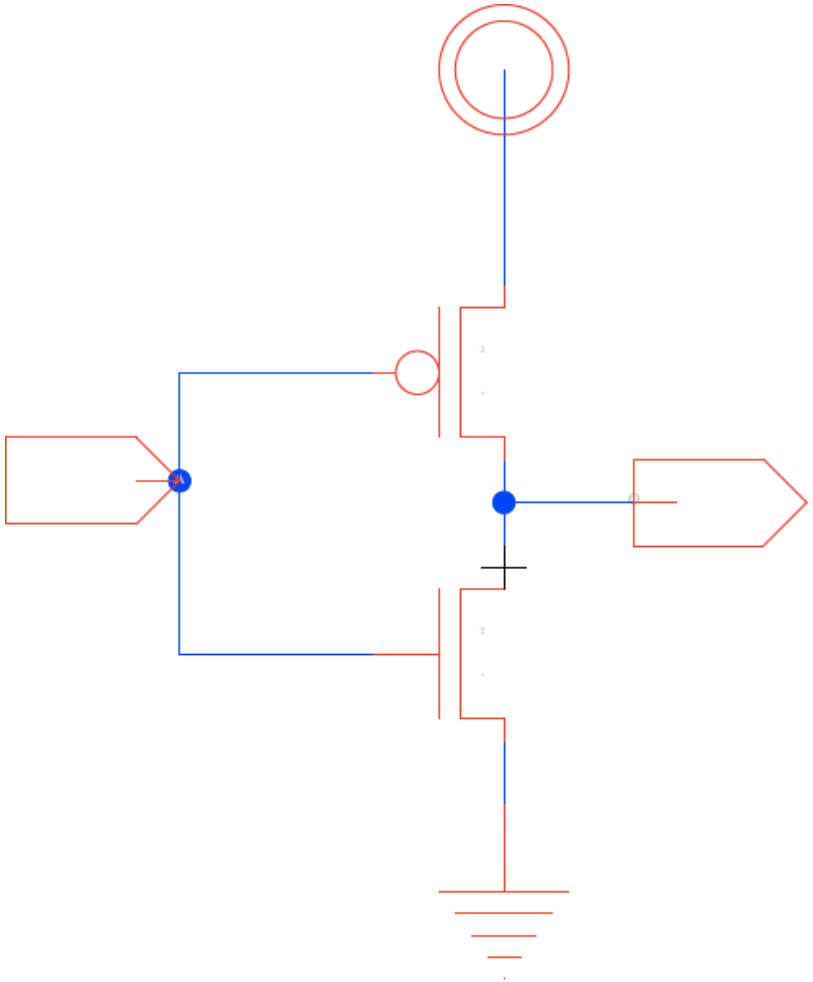




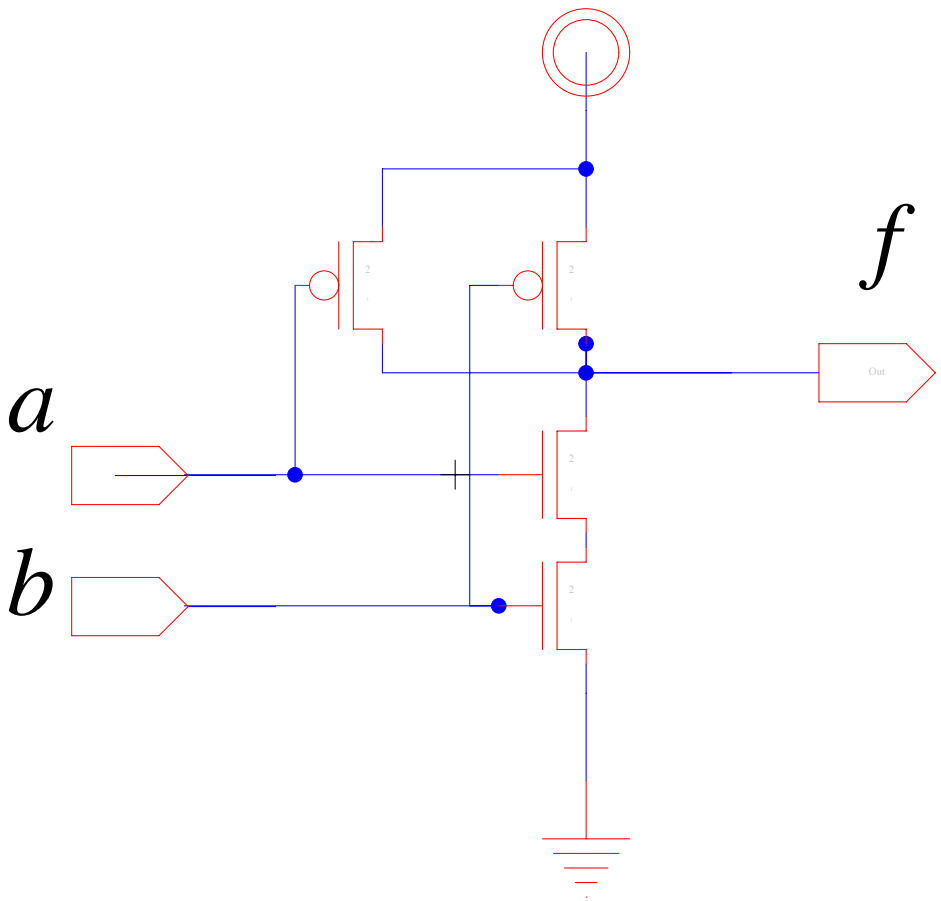
Convince yourself with a truth table.

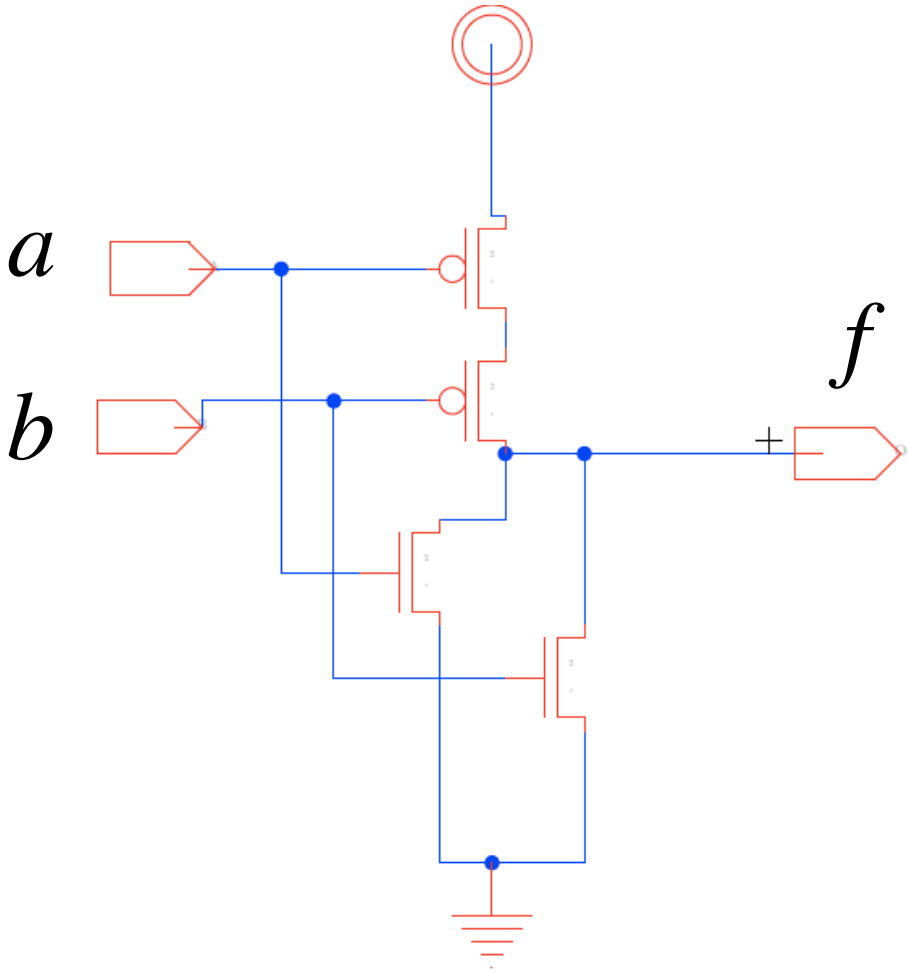
Inverting Stage

- Each stage of Static CMOS gate is inherently inverting



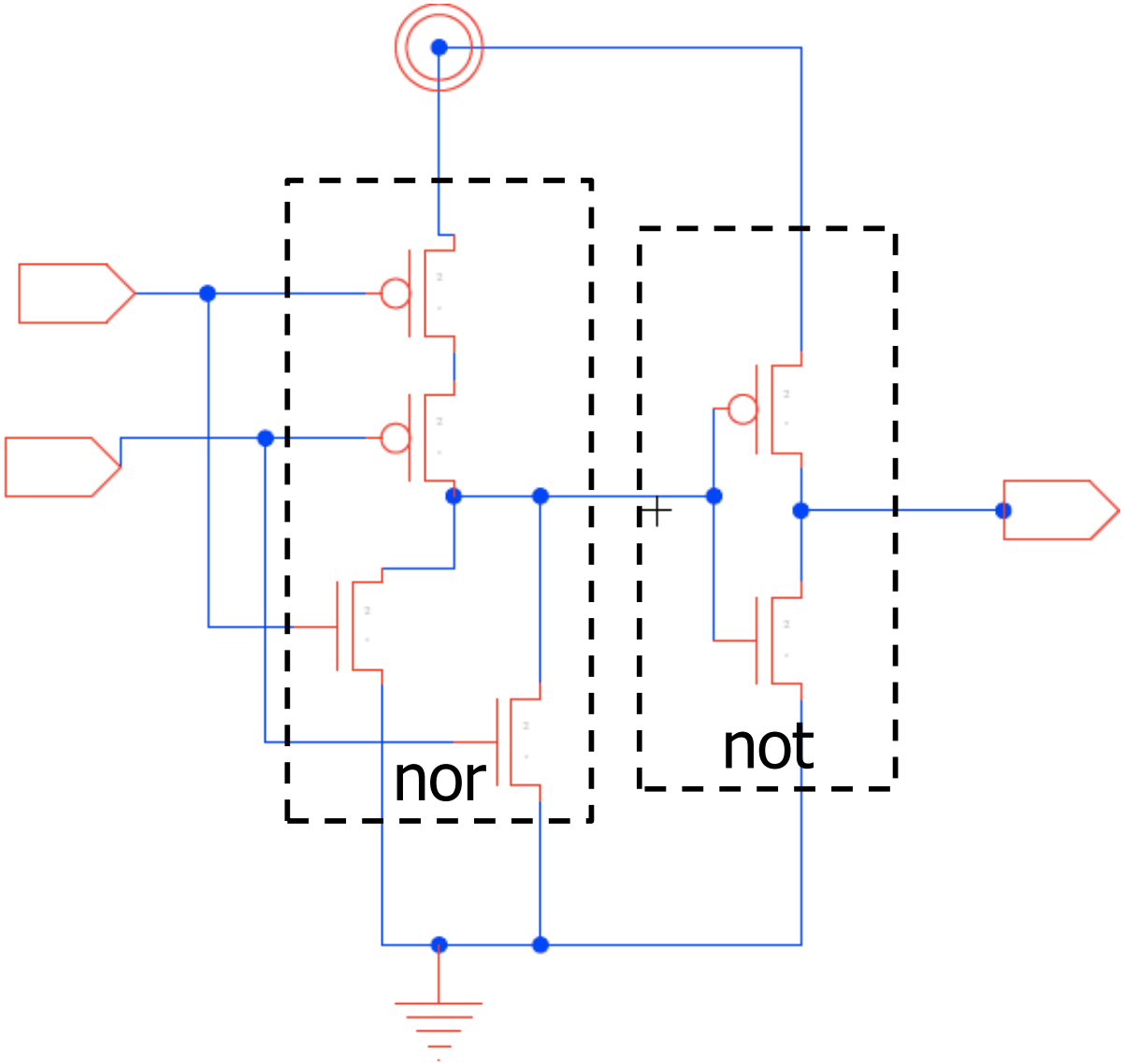
NAND/NOR Fundamental Gates





How implement OR?

How implement OR?



Cascading Stages

- Can always cascade "stages" to build more complex gates
- Could simply build nor2 or nand2 at circuit level and assemble arbitrary logic by combining – universality
  - but may not be smallest/fastest/least power

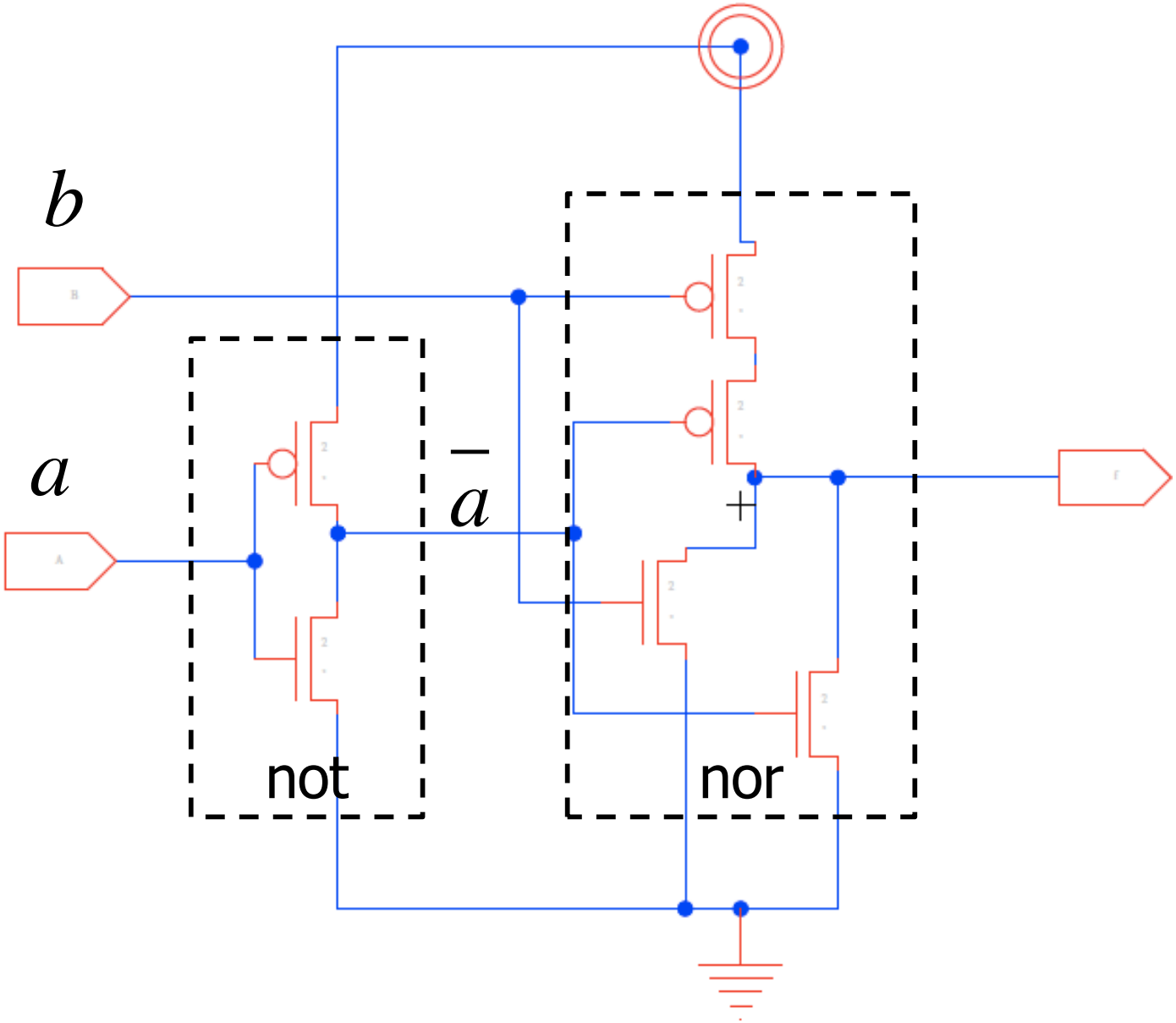
Implement: $f = a \cdot \bar{b}$

- Pullup?
- Pulldown?

Hint: use cascading stages

Implement: $f = a \cdot \overline{b}$

- Pullup?
- Pulldown?

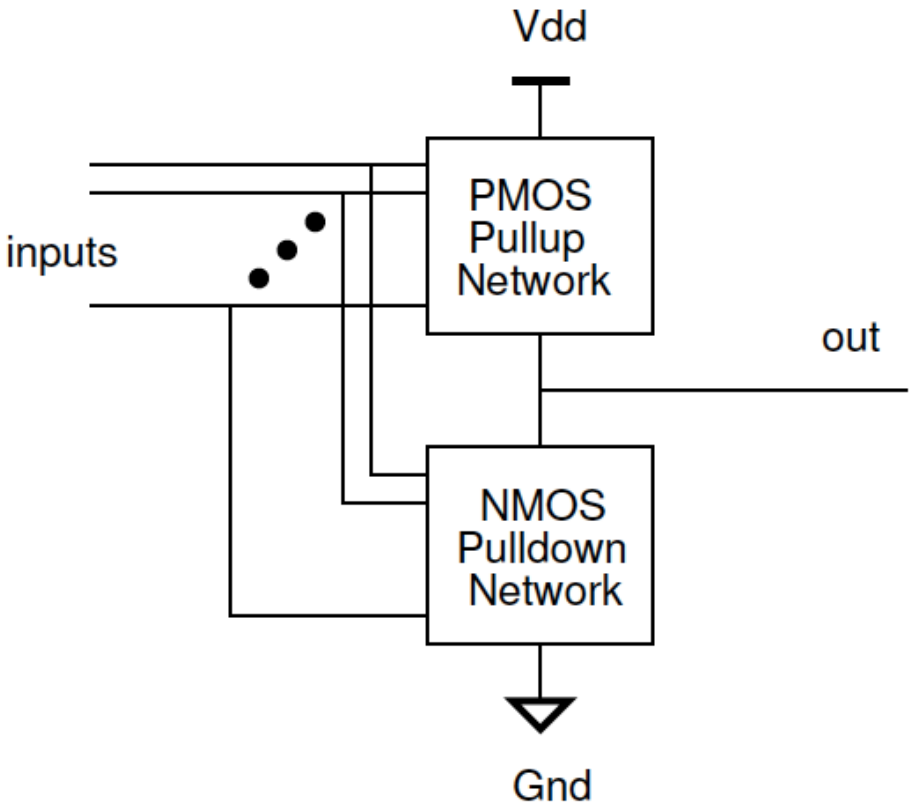


Big Idea

- MOSFET Transistor as switch
- Functionality-driven simplified modeling (Zero order)
  - Aid reasoning
  - Sanity check
  - Simplify design
- CMOS Gate Design
  - Complementary pull-up and pull-down networks

Big Idea

- Systematic construction of any gate from transistors
  1. Use static CMOS structure
  2. Design PMOS pullup for *f*
  3. Use DeMorgan's Law to determine *f'*
  4. Design NMOS pulldown for *f'*



Admin

- HW 1 out – due 1/27
  - Will take time to learn Electric CAD tool, start early
- Monday (1/23) – no lecture, Lab in Detkin
- Wednesday (1/25) regular physical lecture in LRSM 112B
- TA office hours announced on Ed Discussion (Mon- Friday)

Acknowledgement

- Prof. André DeHon (University of Pennsylvania)
- Prof. Tania Khanna (University of Pennsylvania)